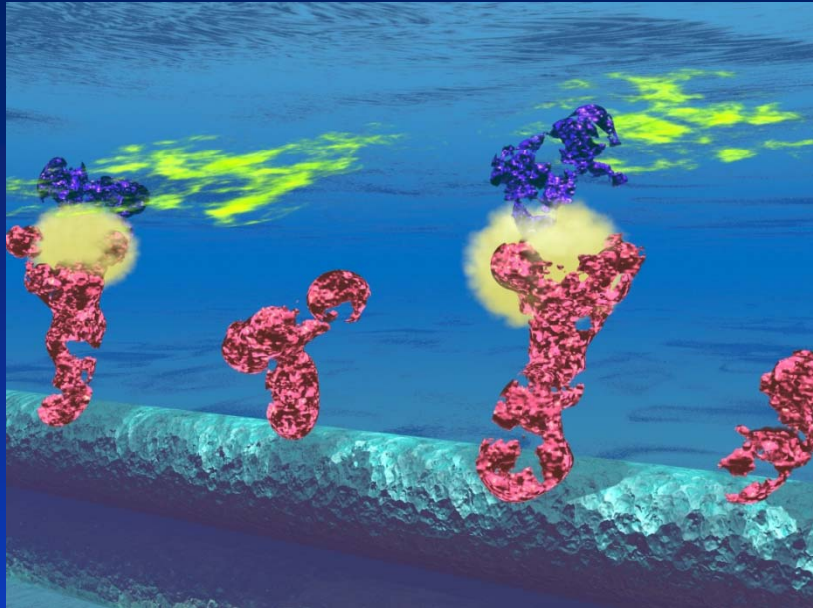


CMOS Nanowire Biosensor Systems

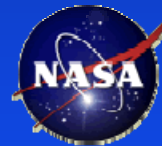
Mark Reed
Yale University



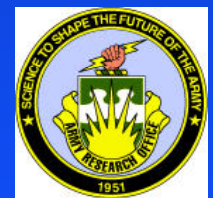
Departments of Applied Physics and Electrical Engineering
Yale Institute for Nanoscience and Quantum Engineering

with: Eric Stern, Alek Vacic, Nitin Rajan,
David Routenberg, Erin Steenblock,
Jason Criscione, Jason Park,
Prof. Tarek Fahmy

Thanks to: Jin Chen, James Klemic,
Daniel Turner-Evans, Pauline
Wyrembak , Cathy Jan
Labs of Profs. Ronald Breaker,
Andrew Hamilton, Tarek Fahmy

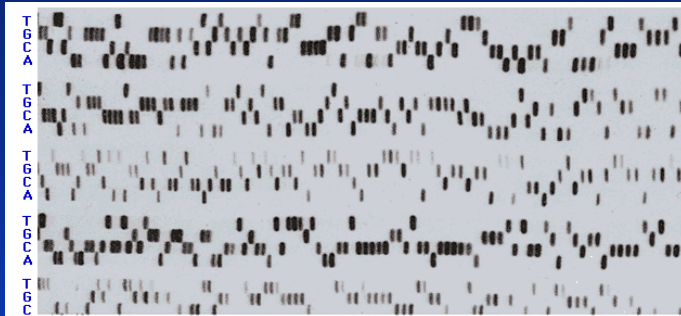


Yale Institute for Nanoscience
and Quantum Engineering

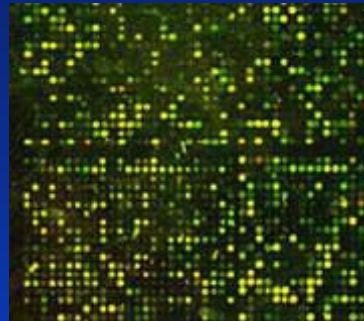


Current Macromolecular Sensing

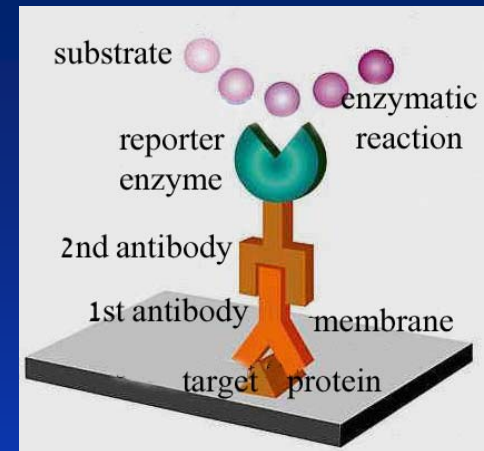
Labeled sensing



DNA sequencing, radiotag

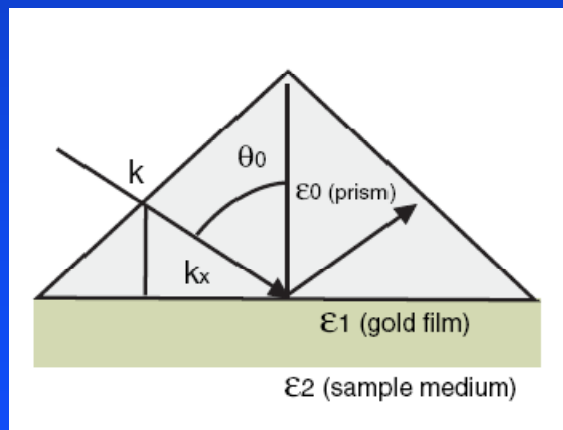


DNA array, fluor

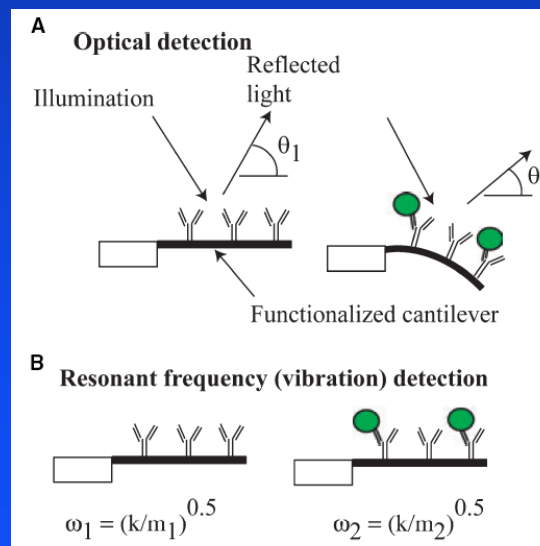


ELISA: Indirect fluor

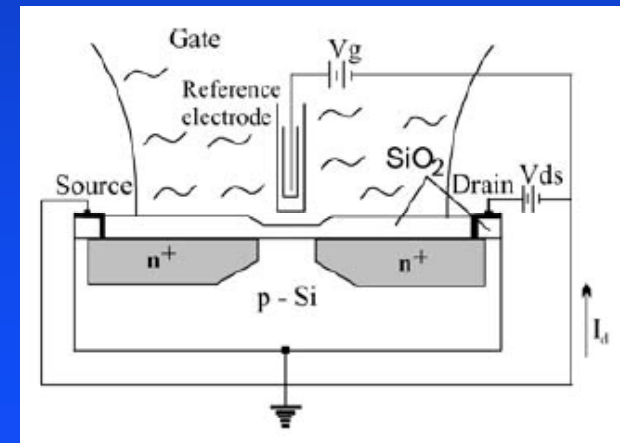
Unlabeled sensing



Surface plasmon resonance

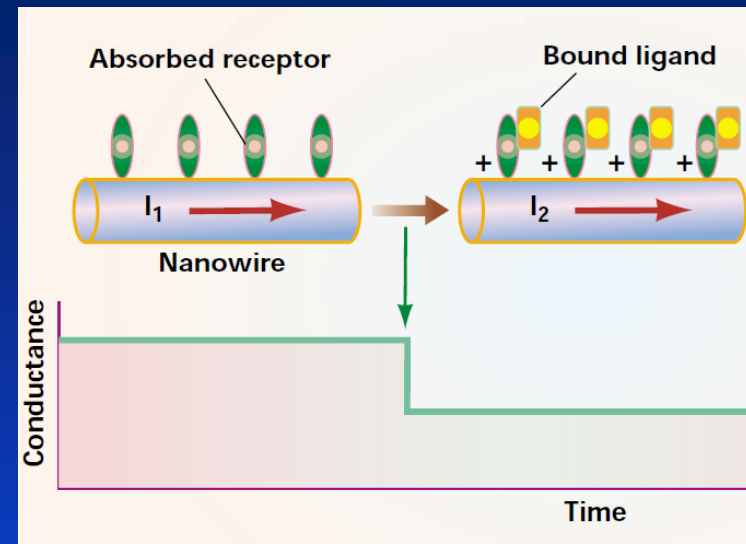
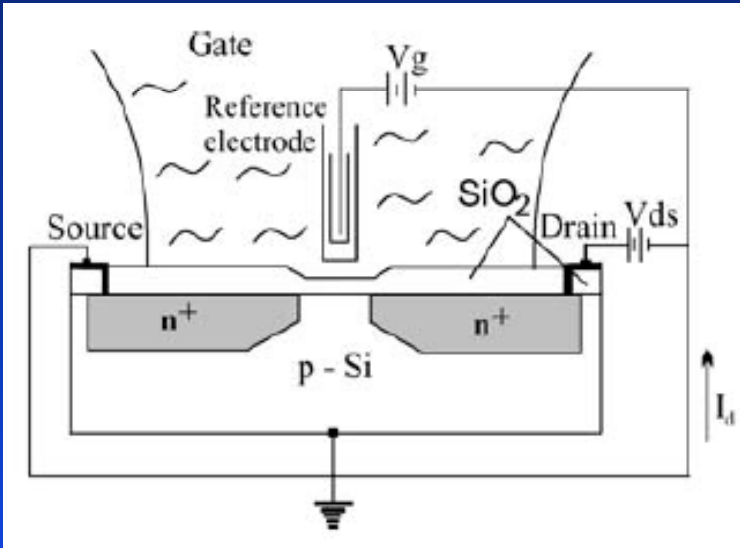


Suspended cantilever



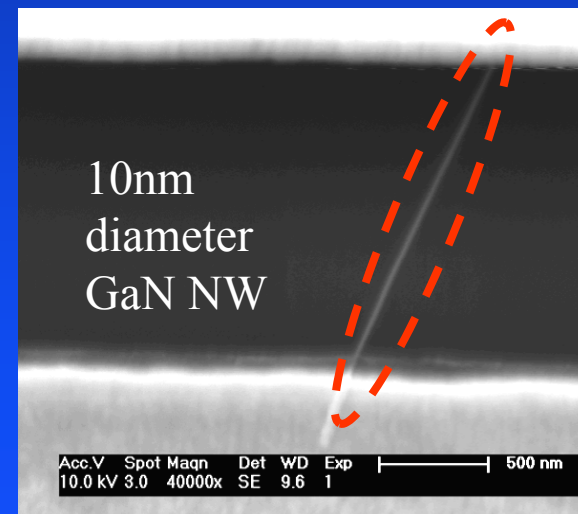
Electrical : ISFET

Nanowire biosensors (unlabeled detection)

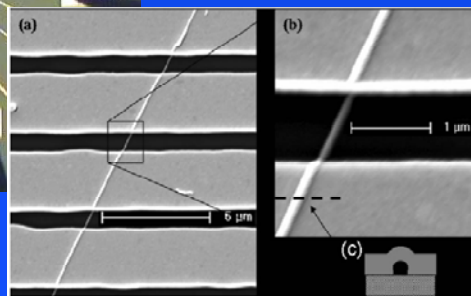
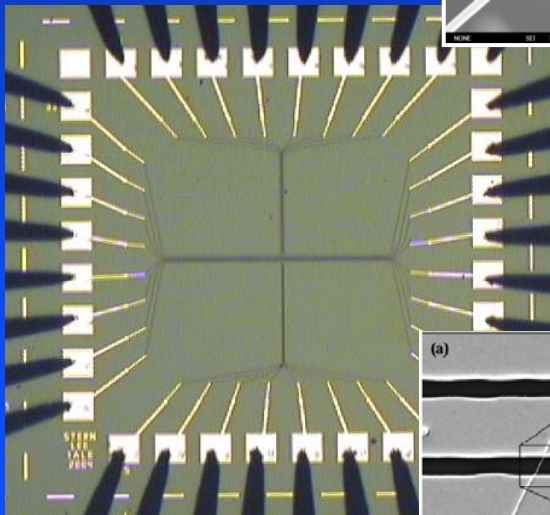
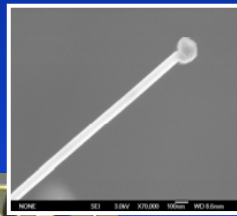
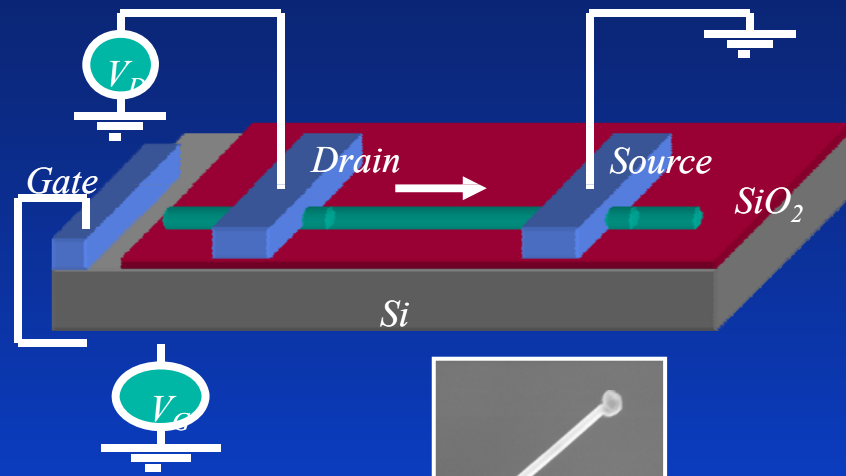


ISFETs detection limits
typically $\sim \mu\text{M}$

$$\frac{1}{I} \frac{dI}{dQ} \sim \frac{1}{r}$$

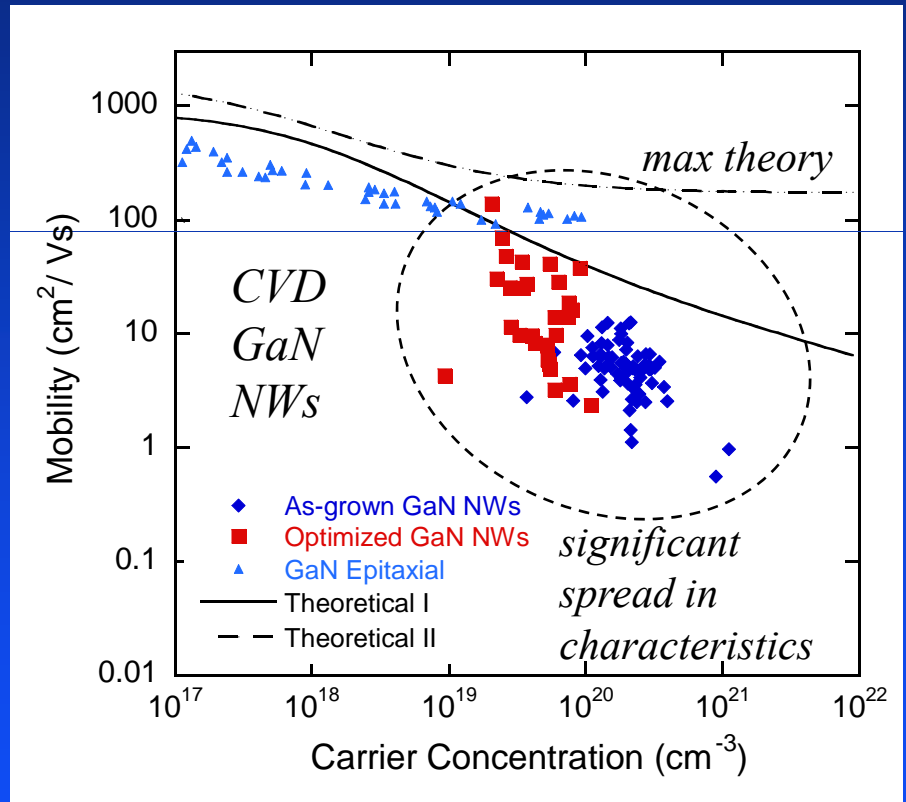


Vapor-Liquid-Solid (VLS) nanowire FETs



J. Vac. Sci. Technol. **B24**, 231 (2006).

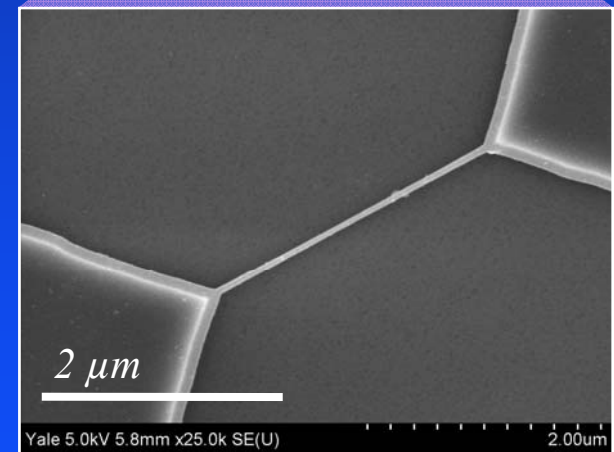
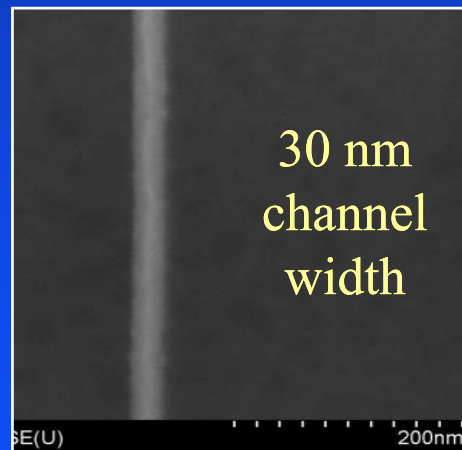
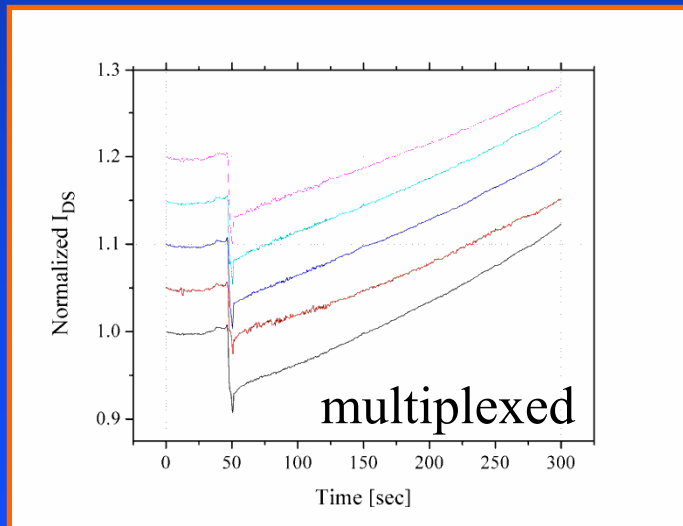
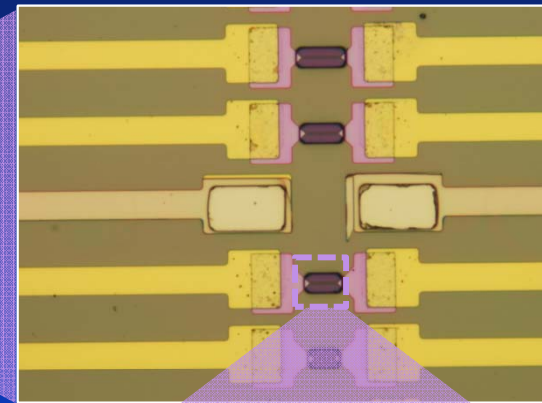
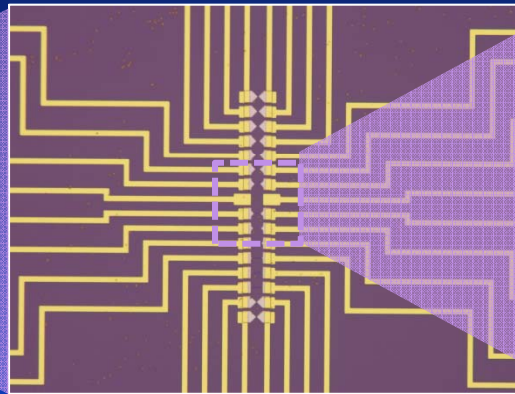
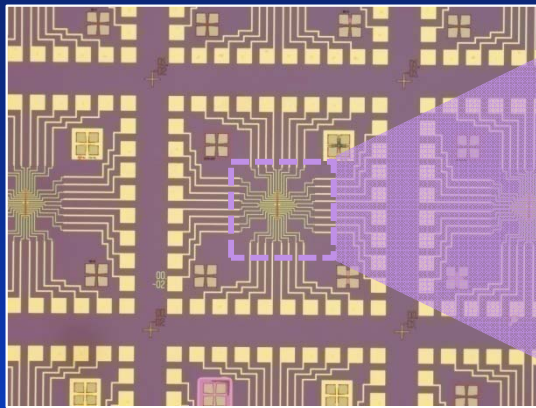
NW mobilities vs theoretical limits, epi



Braz. Jour. Phys. **36**, 824 (2006).

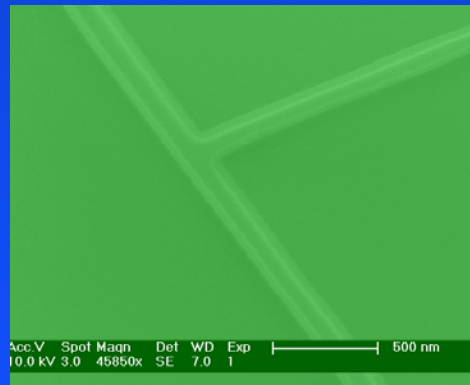
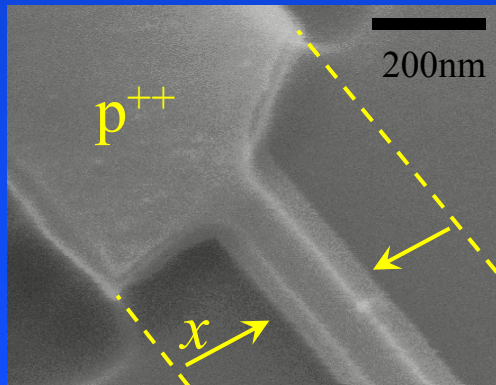
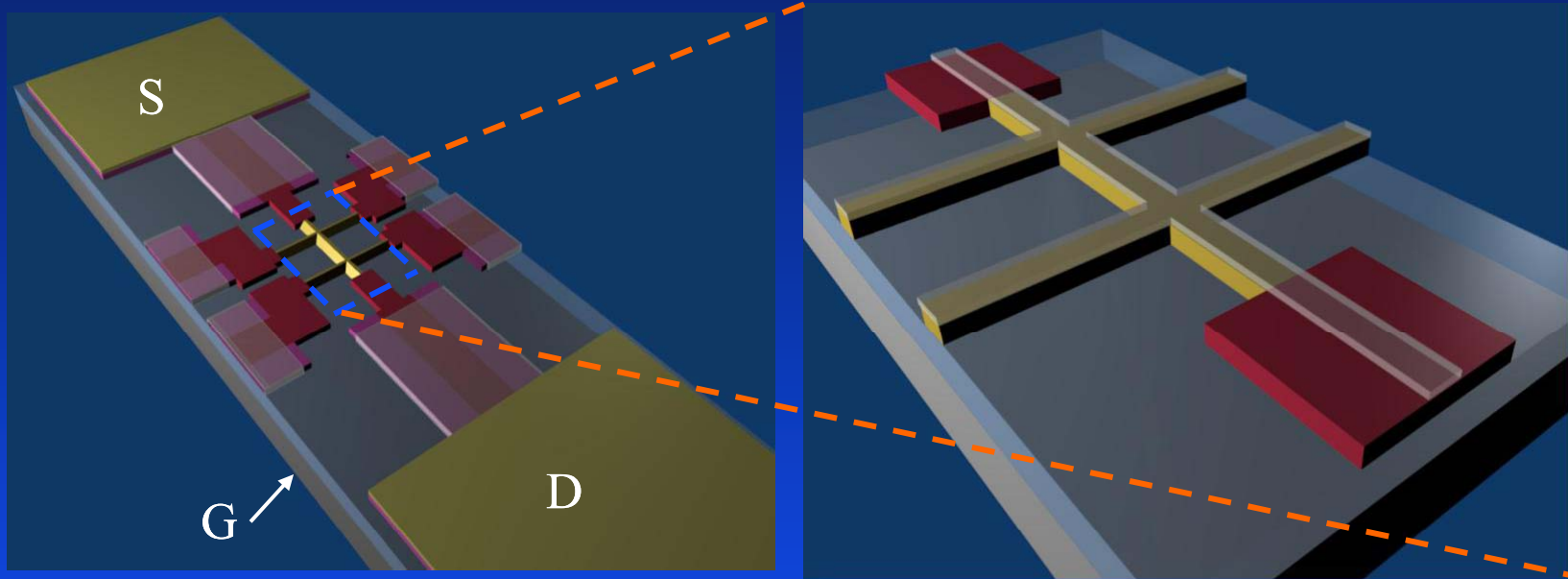
Appl. Phys. Lett. **88**, 053106 (2006).

Silicon-on-insulator (SOI) CMOS Nanowires

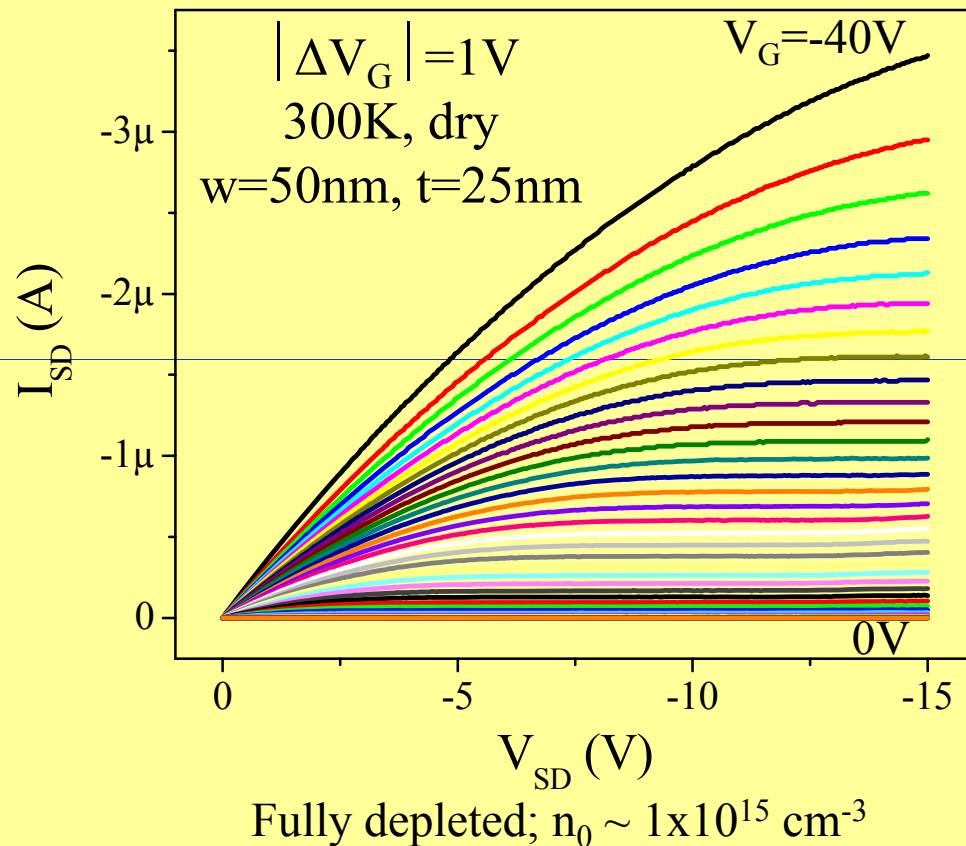


anisotropic etching

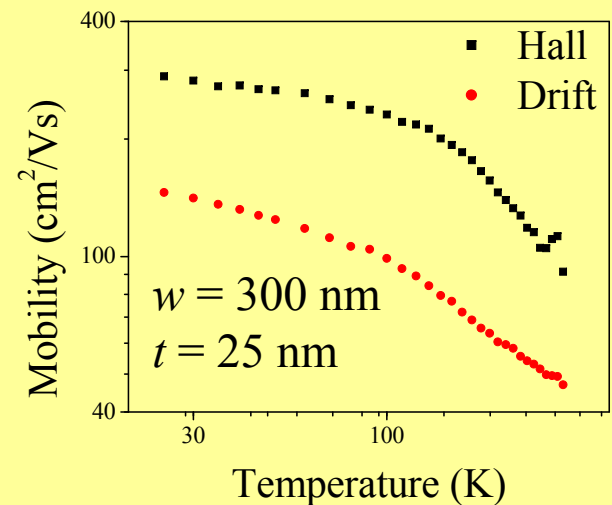
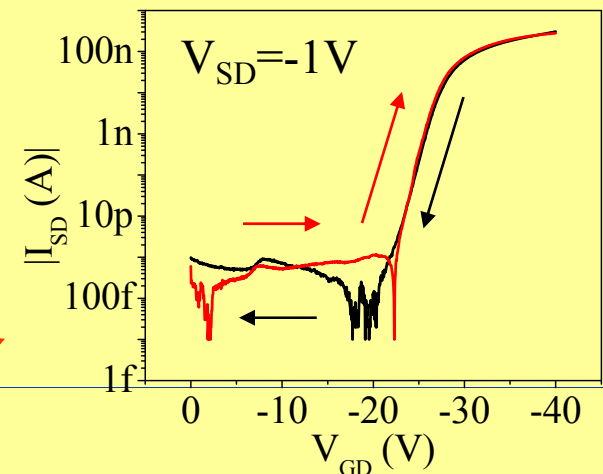
$(100)/(111)$ etch rates $\sim 1000:1$, $dx_{(111)}/dt \sim 3\text{\AA}/\text{sec}$



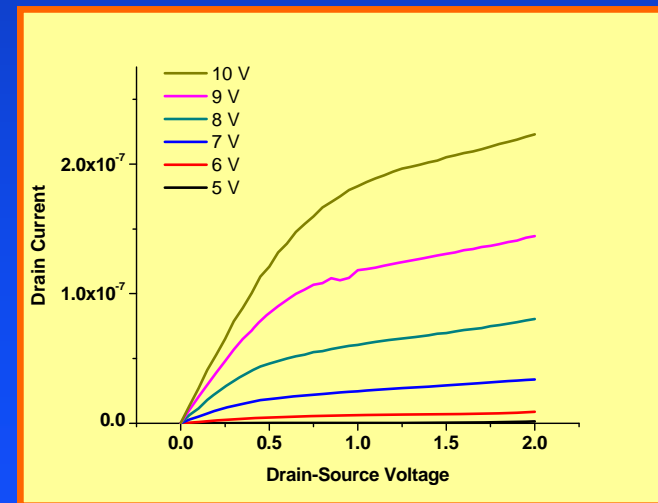
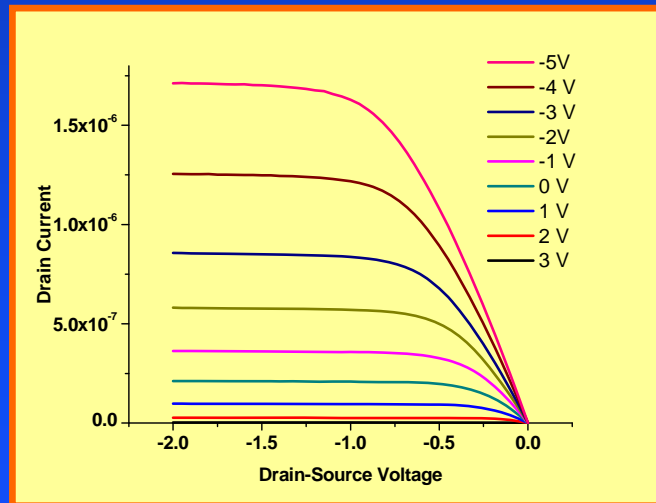
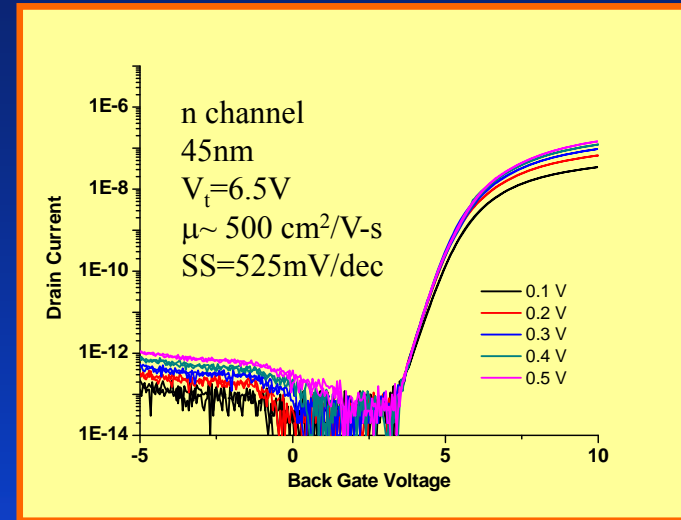
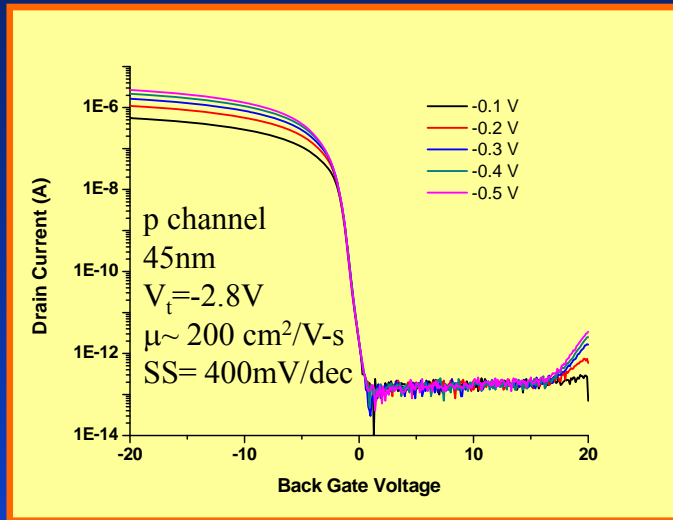
p-type accumulation mode (backgate) – 1st gen



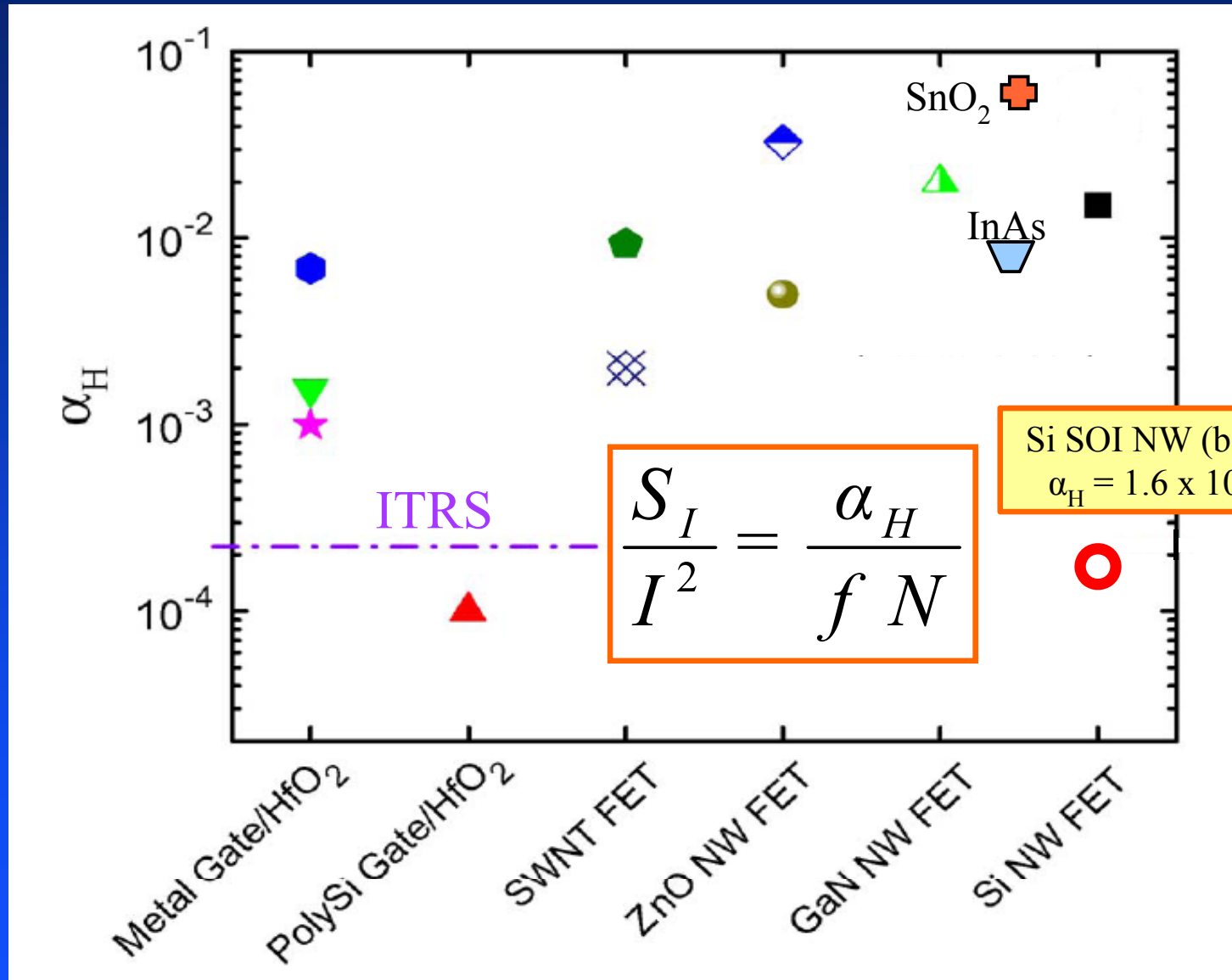
$\bar{\mu} = 54 \text{ cm}^2/\text{V-s}$ $\mu_{\text{max}} = 139 \text{ cm}^2/\text{V-s}$



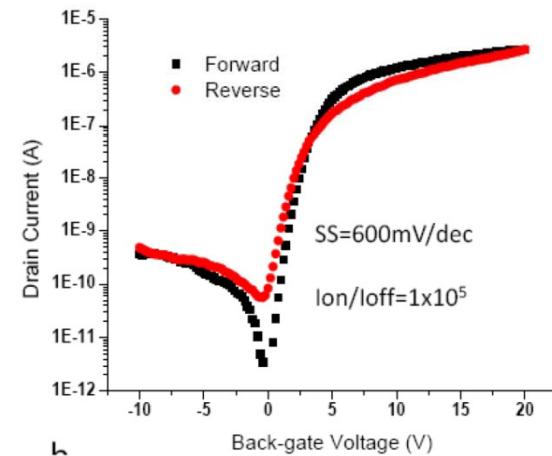
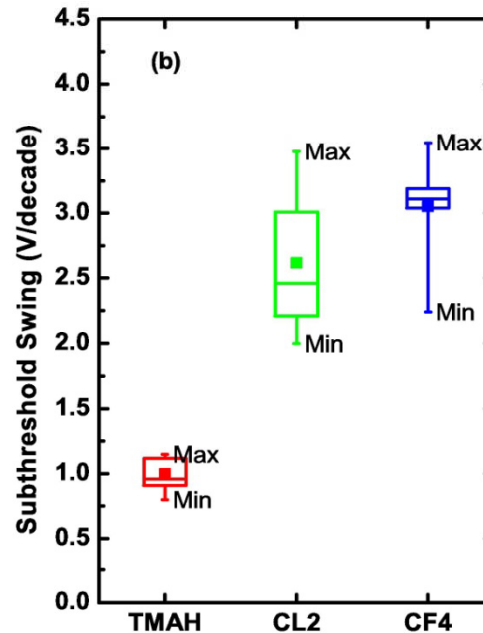
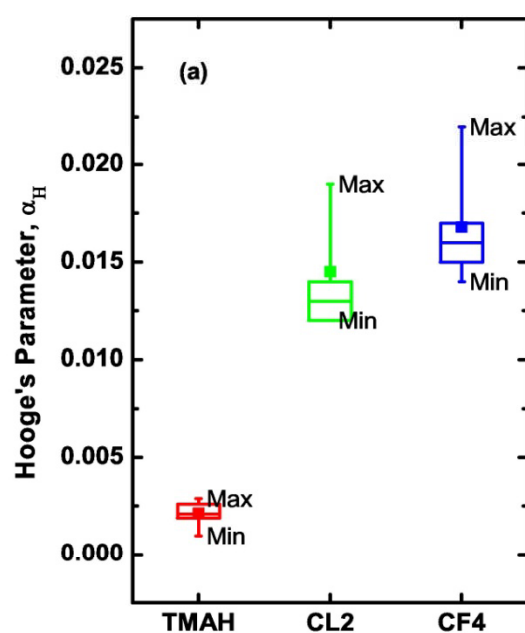
Complimentary devices – 2nd gen



1/f noise of nanowires



Etch Process-Noise Correlation



$$S = 2.3 \frac{kT}{q} \frac{(C_{ox} + C_{it} + C_d)}{C_{ox}}$$

Etch Type	TMAH	Cl ₂	CF ₄
μ _{FE} (cm ² /V•s)	170	180	100
Std. Dev. (cm ² /V•s)	10	50	20

N. K. Rajan *et al*, *Elect. Dev. Lett.* **31**, 615 (2010).

Operating Point

Linear Region:

$$\frac{dI_D/dV_0}{I_{D,initial}} = \frac{\beta V_{ds}}{\beta \left[V_0 V_{ds} - \frac{1}{2} V_{ds}^2 \right]} = \frac{1}{\left[V_0 - \frac{1}{2} V_{ds} \right]}$$

$$\beta = C_{ox} \mu W / L$$

$$V_0 = V_{gs} - V_t$$

Subthreshold Region:

$$\frac{dI_D/dV_g}{I_{D,initial}} = \frac{\frac{q\eta}{kT} I_{D0} \exp\left[\frac{qV_{gs}\eta}{kT}\right]}{I_{D0} \exp\left[\frac{qV_{gs}\eta}{kT}\right]} = \frac{q\eta}{kT} = \frac{1}{S}$$

$$\eta = \frac{d\phi_s}{dV_{gs}} = \frac{1}{1 + (C_d/C_{ox})}$$

example

In Subthreshold Region

Subthreshold Swing = 190 mV/dec

S = 1/SS = 5.3

pH Response = 0.3 Dec/pH

In Linear Region

$G_m = 8.2 \times 10^{-6}$

$I_D = 8.0 \times 10^{-6} \times \text{Overdrive Voltage}$

$S = G_m / I_D = 1.03 / V_O$

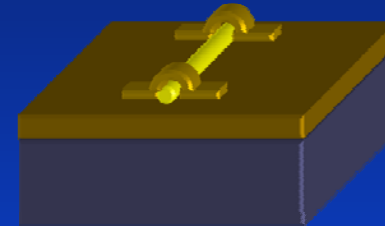
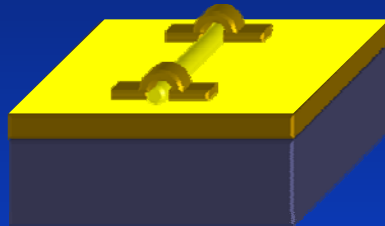
pH Response = 0.062/ V_O Dec/pH

At 1 volt overdrive, sensitivity is decreased by 5X

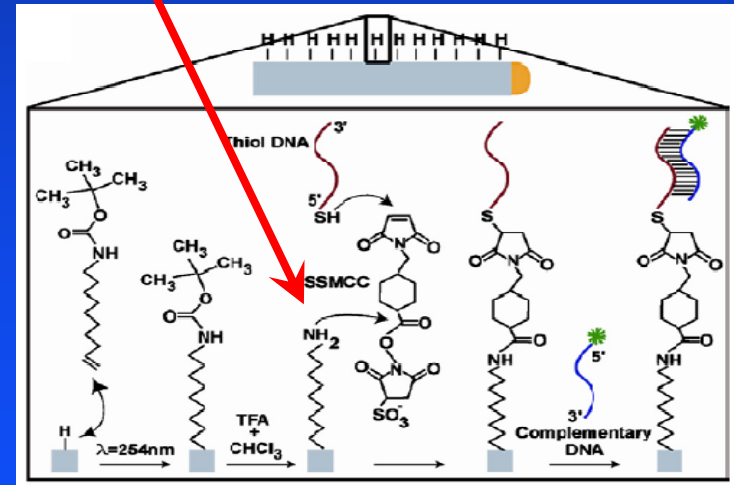
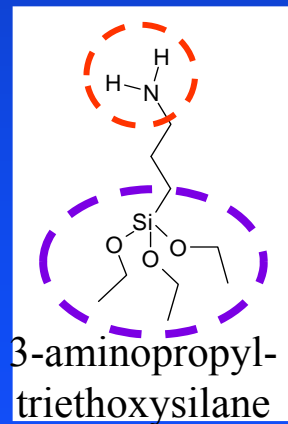
Selective Functionalization

Dec-9-enyl-carbamic acid tert-butyl ester

APTES

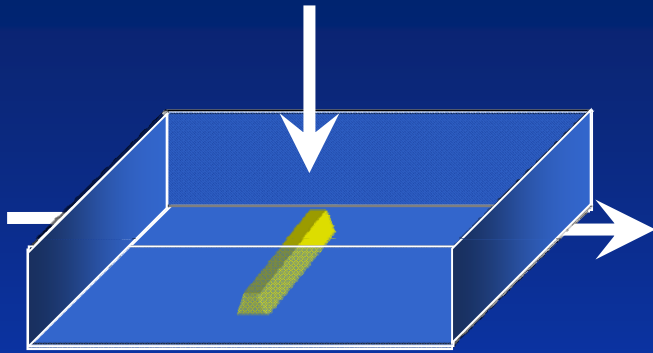


Ratio of Si sensor area to parasitic important

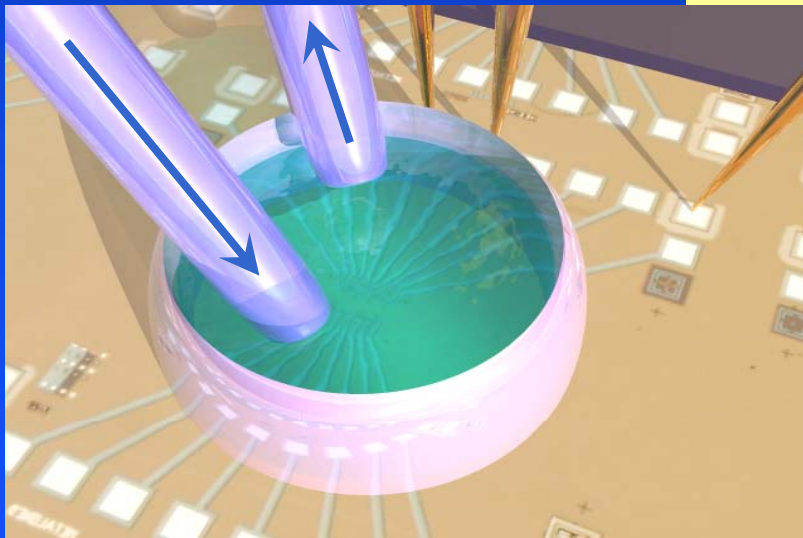
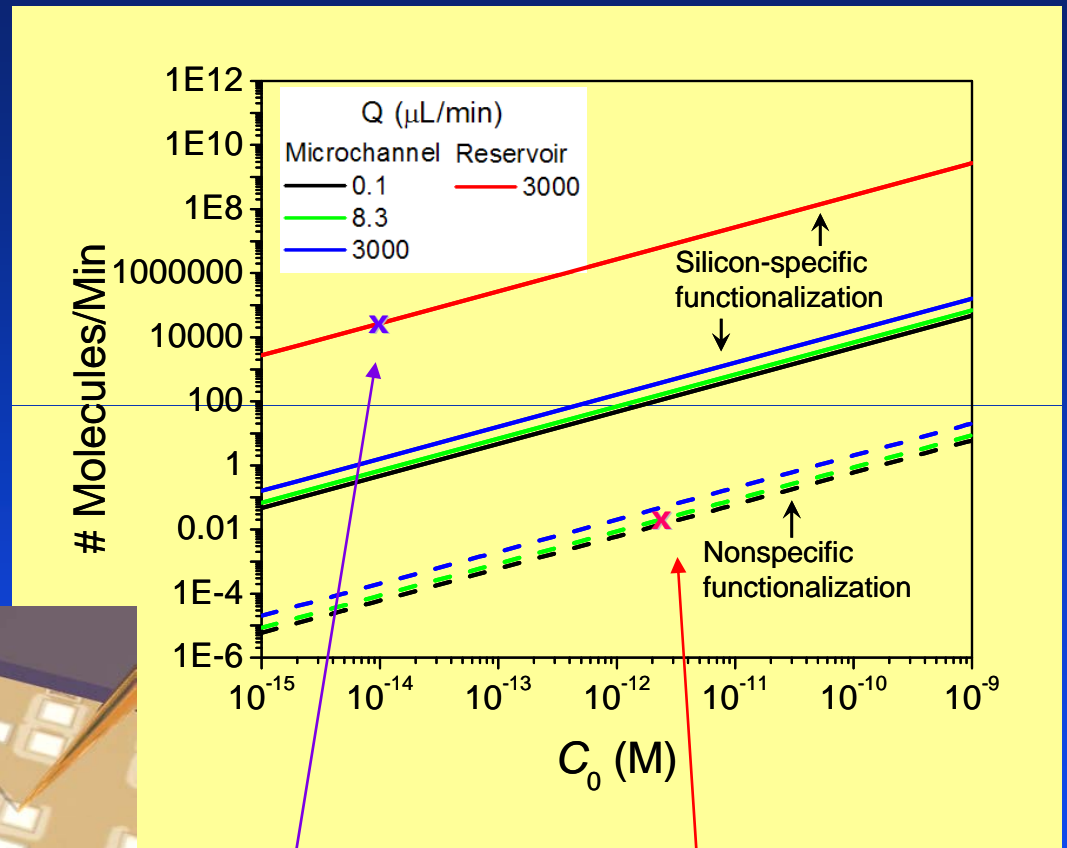


Fluid Considerations

Nano Lett **5**, 803 (2005)



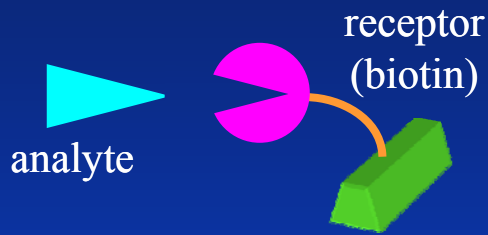
$$J_z = -D \frac{d^2 C_0}{dz^2} + u_z C_0$$



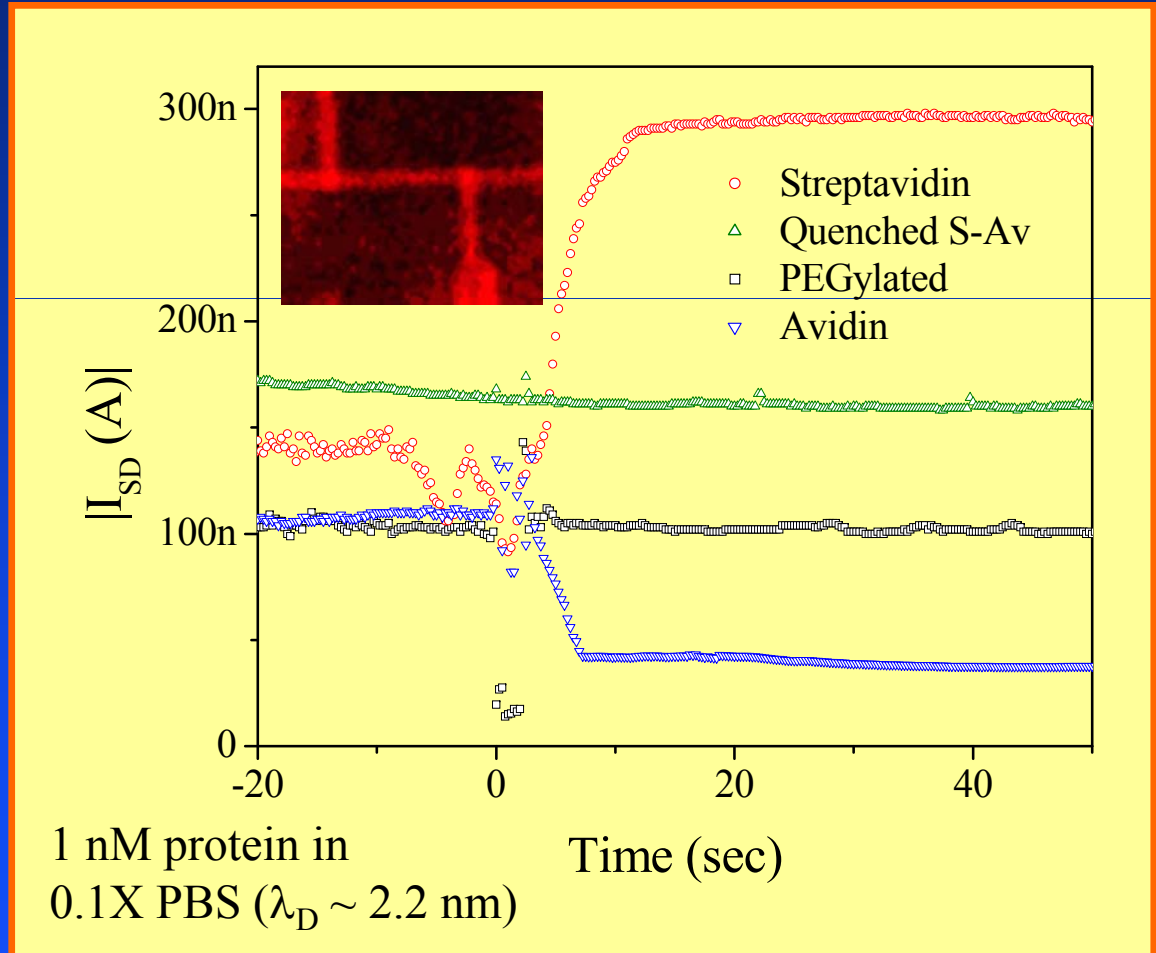
x = microfluidics
Science **293**, 1289 (2001)

x = mixer (reservoir)
Nature **445**, 519 (2007)

Biotin-Avidin & Streptavidin Sensing

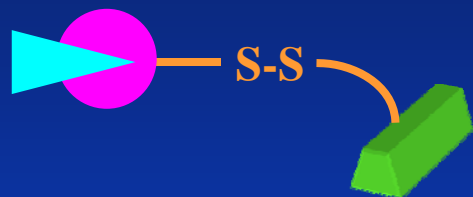


- p-type accumulation mode, biotinylated NW device
- avidin
 - ◆ positive charge
 - ◆ \Rightarrow current decrease
- streptavidin
 - ◆ negative charge
 - ◆ \Rightarrow current increase
- poly(ethylene glycol) (PEG)-ylated device, quenched avidin controls

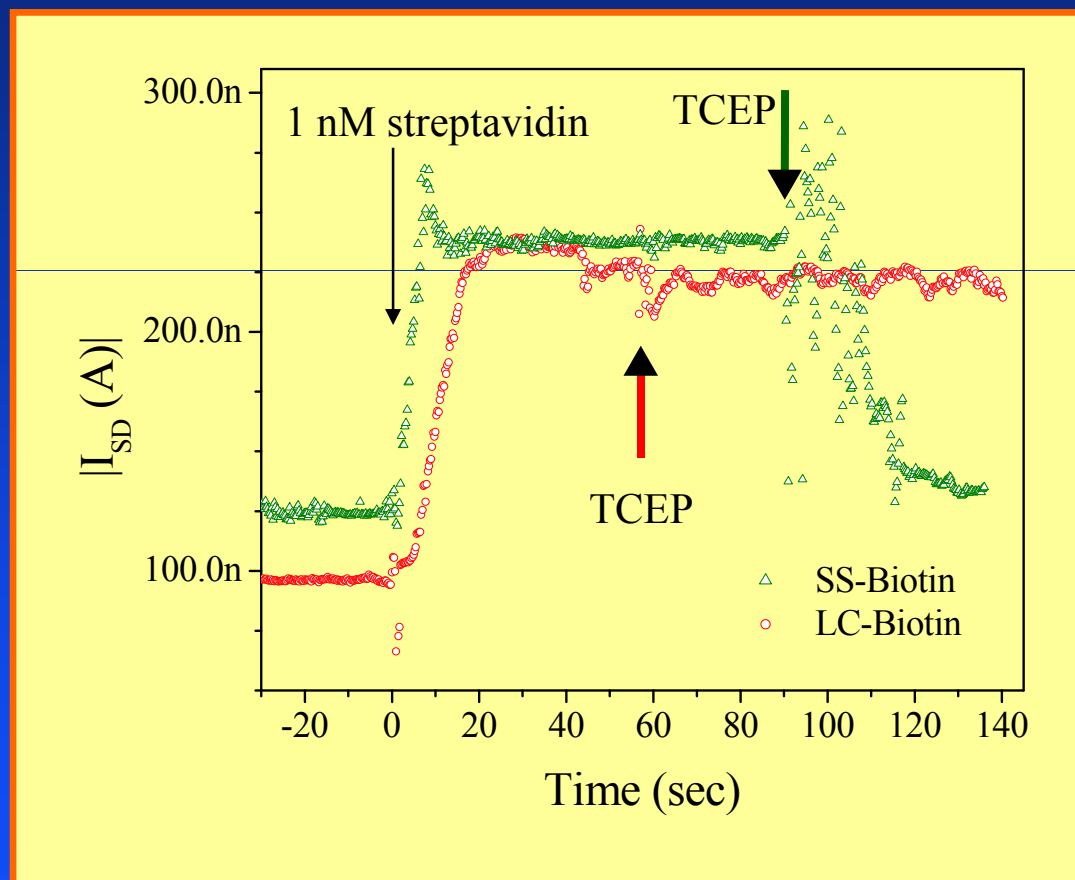


Nature, **445**, 519 (2007)

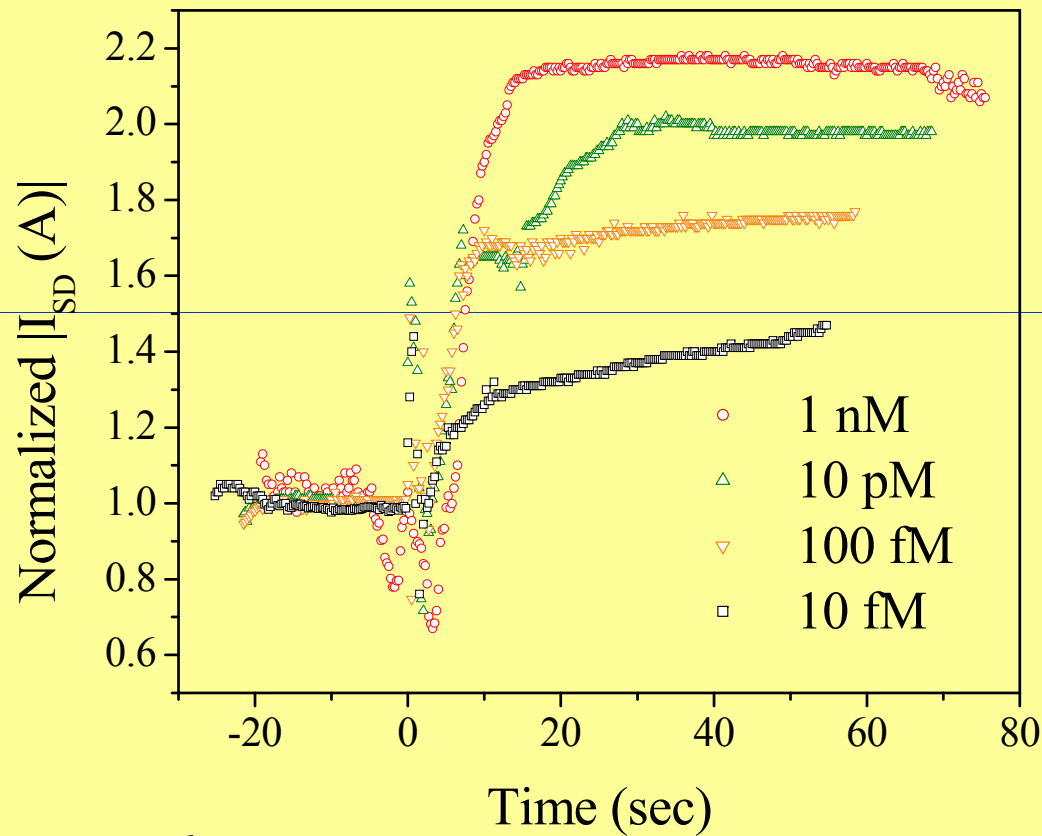
Proving Protein Presence: Cleavage Response



- p-type accumulation
- Red: functionalization with LC-biotin (inert PEG linker)
- Green: functionalization with SS-biotin (dithiol linker)
- Arrow: Addition of reducing agent TCEP (tris(2-carboxyethyl)phosphine)
- SS-biotin functionalized sensor exhibits cleavage



Sensitivity: Concentration Dependence



DC, ambient

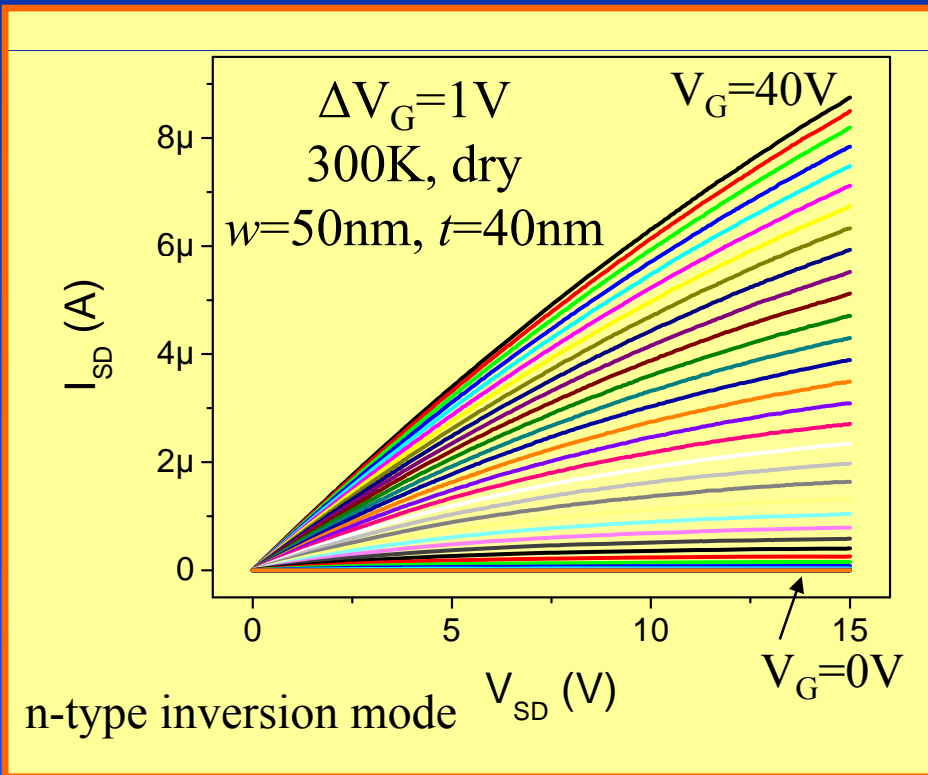
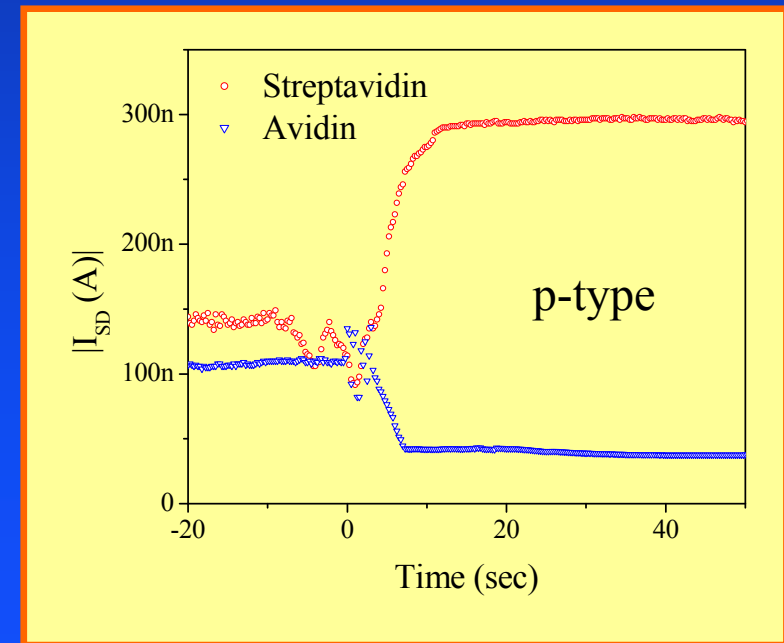
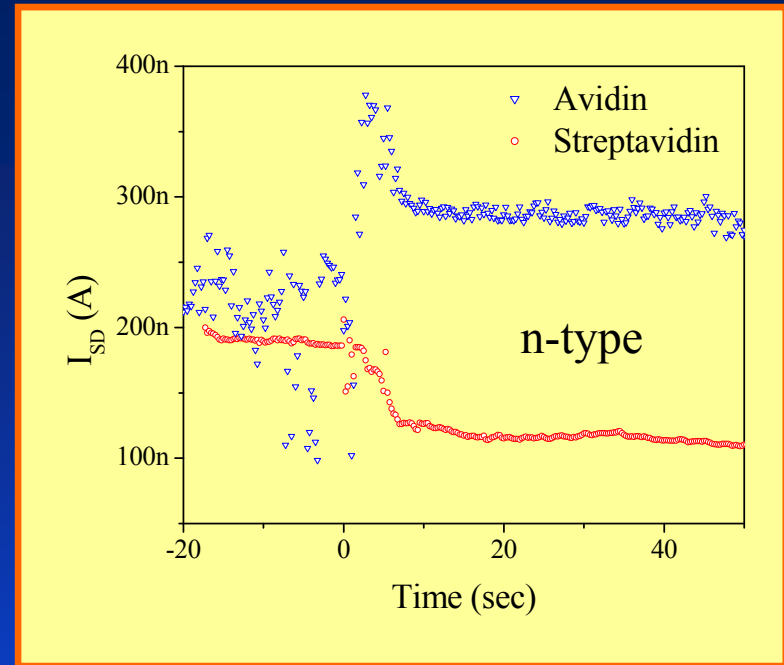
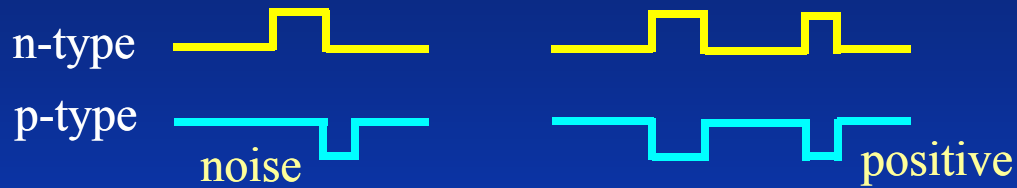
- initial S/N
~ 140 (@10fM)

⇒ <100 aM limit
(< 3 fg/ml)

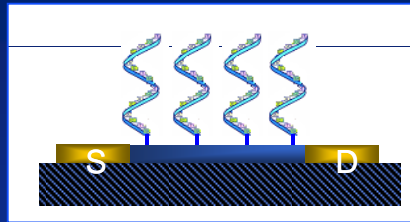
(1 aM = 30
molecule per mm^3)

Complementary Sensing

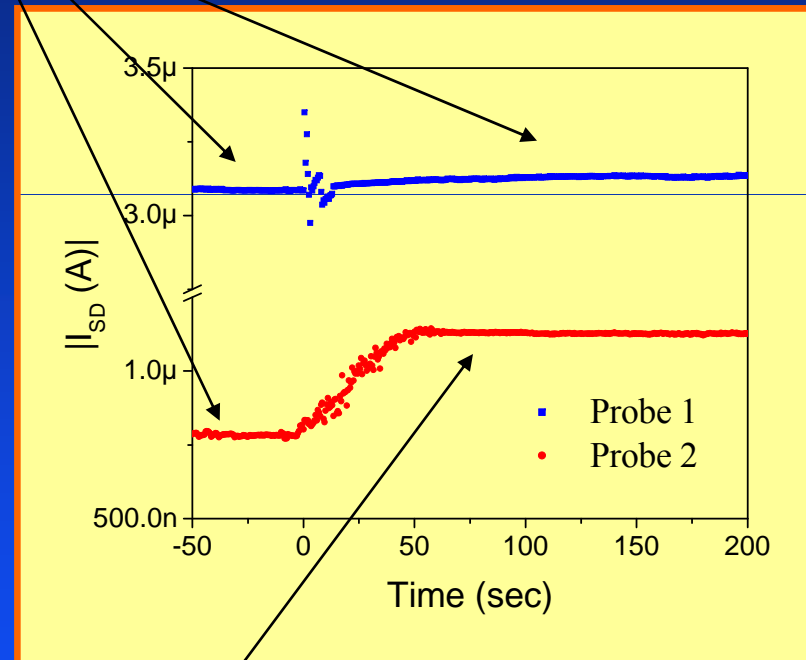
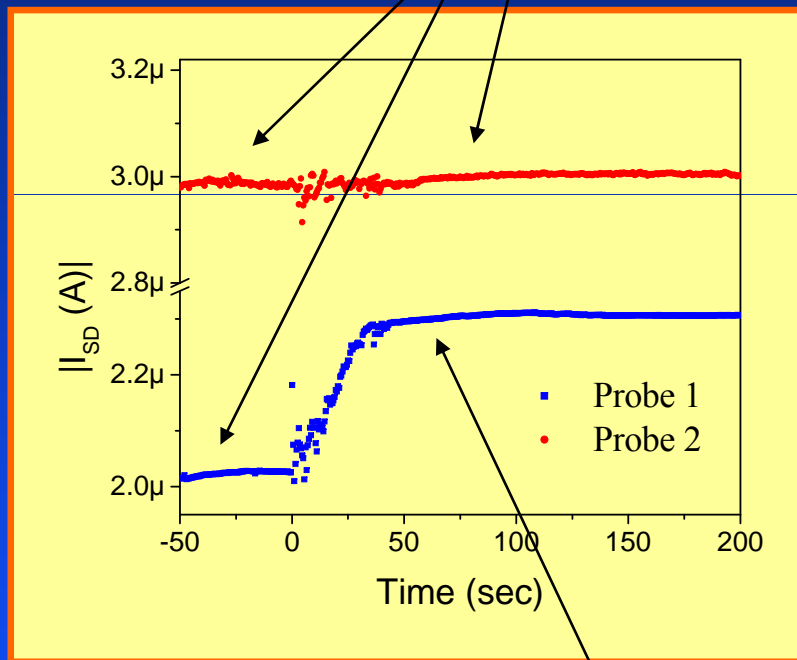
- Critical for error detection
- n-type inversion (on same wafer)



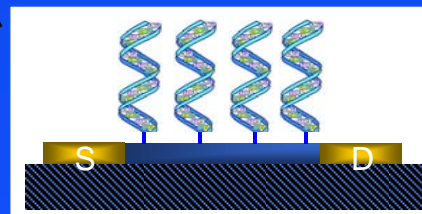
DNA sensing: criss-cross



- Capture1 is the complementary strand of Probe1;
- Capture2 is the complementary strand of Probe2

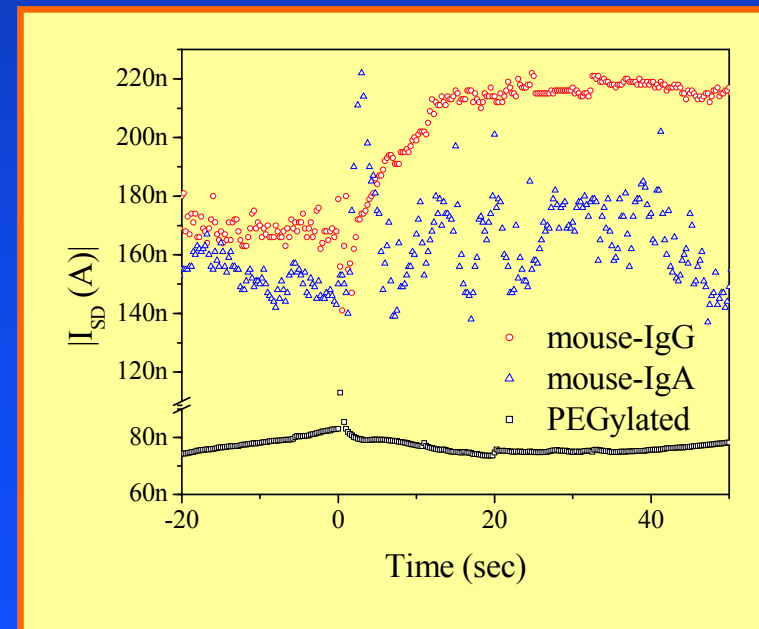
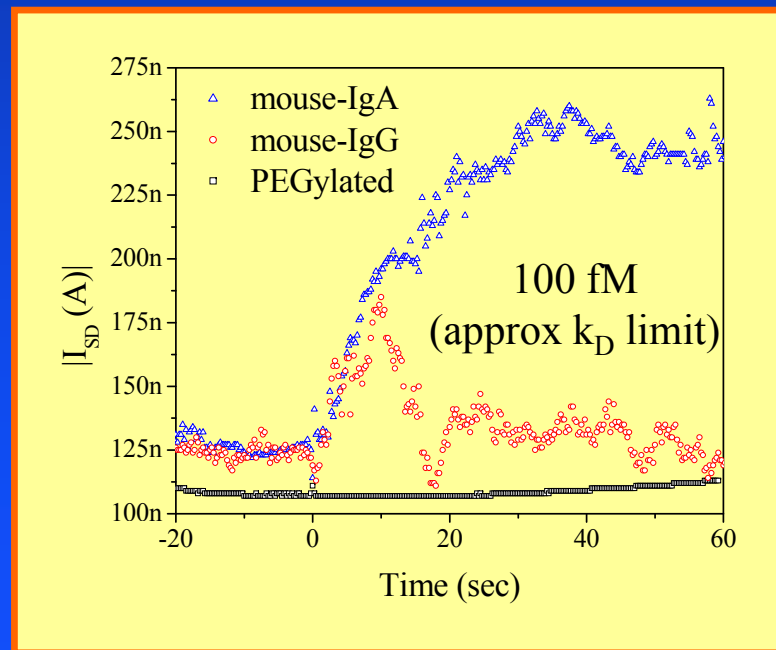
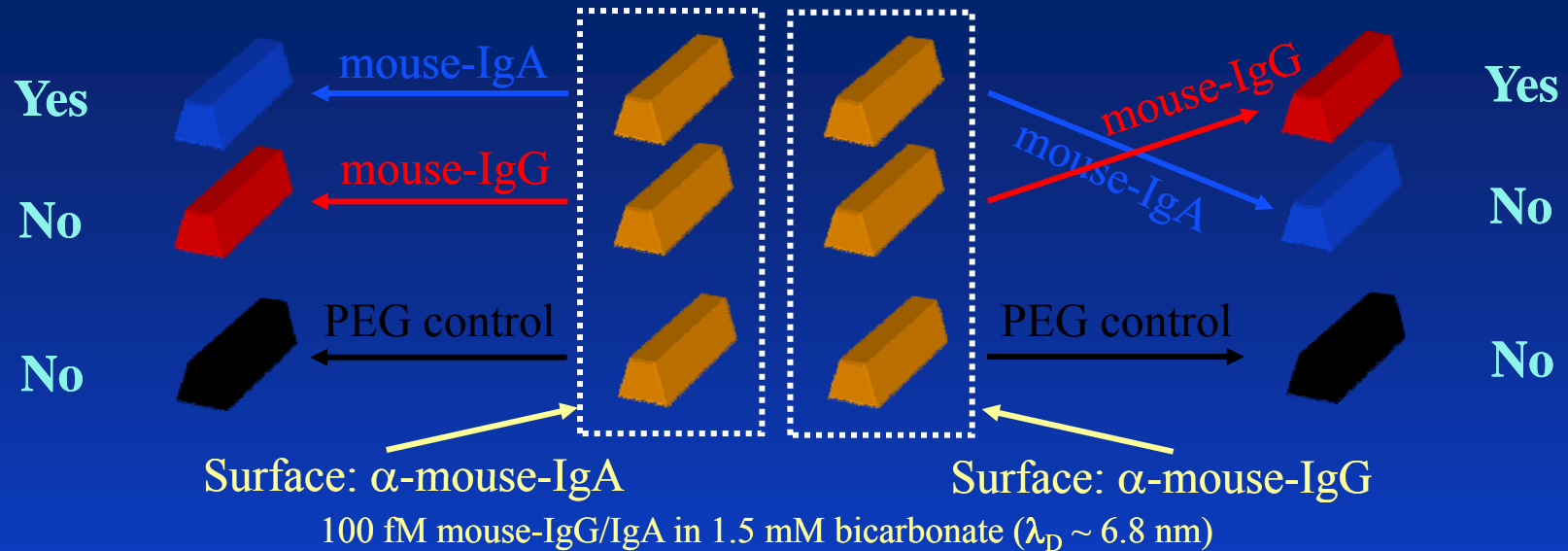


Surface: Capture1



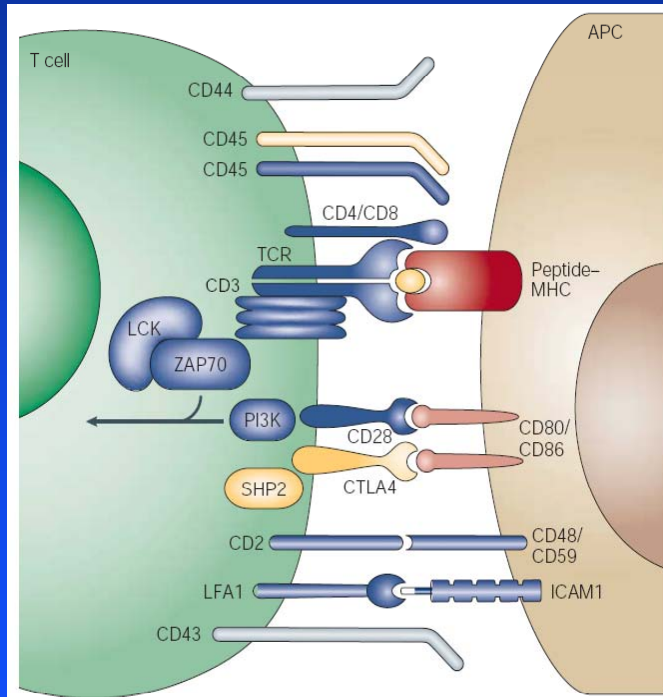
Surface: Capture2

Crisscross Protein Assay: Antibody-Antigen Specificity

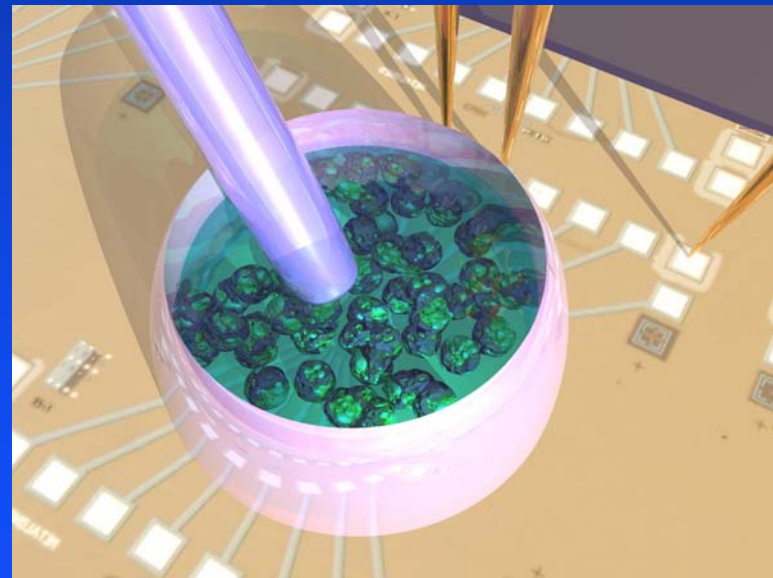
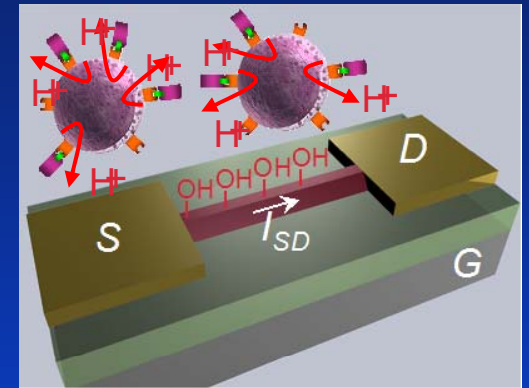
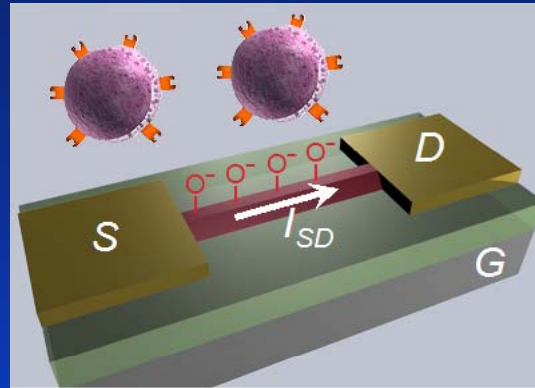


Unlabeled Cellular Detection

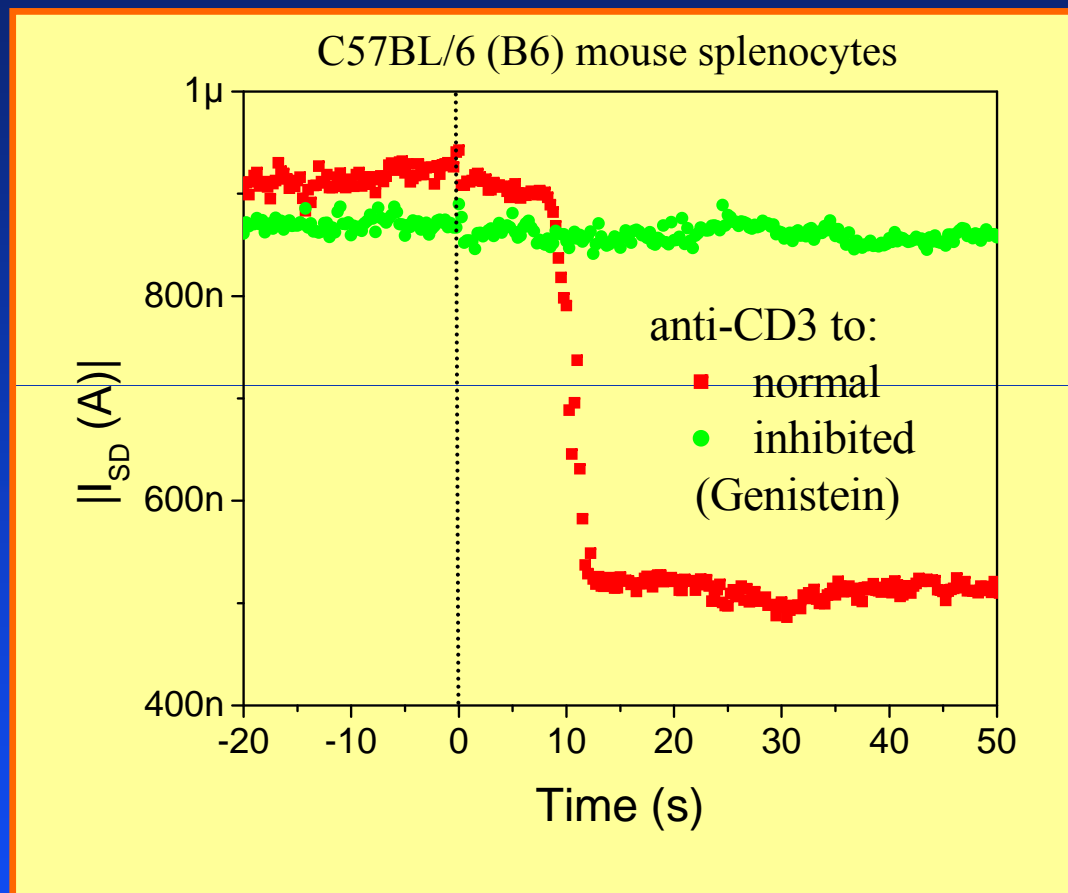
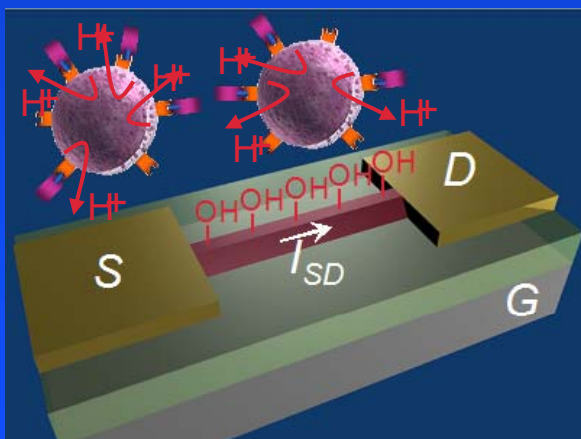
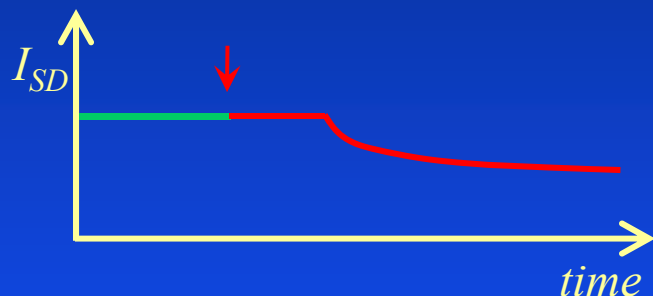
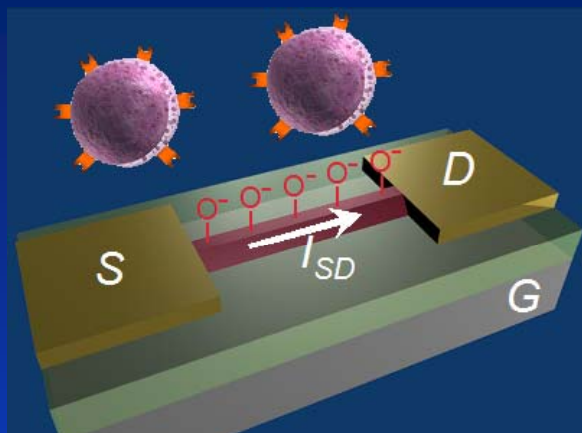
- Most cells (including pathogenic) release H^+ in response to specific stimulation



Nat Rev Immunol 3 (2003) 973



T-lymphocyte activation

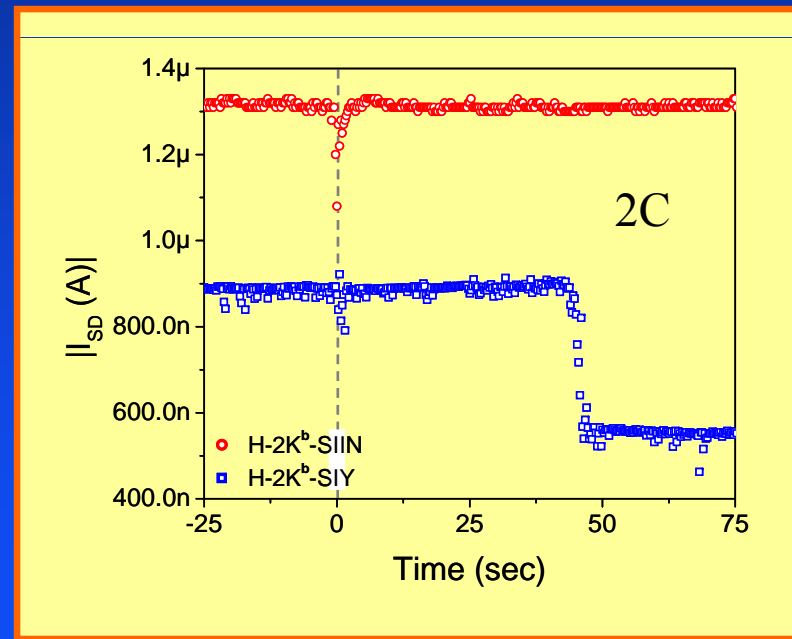
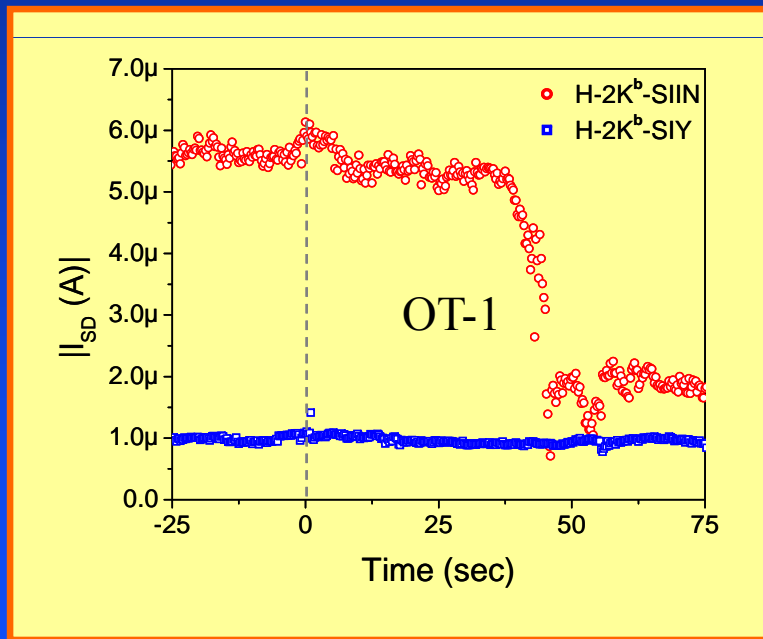


Real-time measurement of cell immune response dynamics

Transgenic peptide-specific MHC T-cell response

OT-1/2C transgenic murine CD8⁺ T-cells

- OT-1 reacts to H-2K^b-SIIN, not H-2K^b-SIY
- 2C reacts to H-2K^b-SIY, not H-2K^b-SIIN

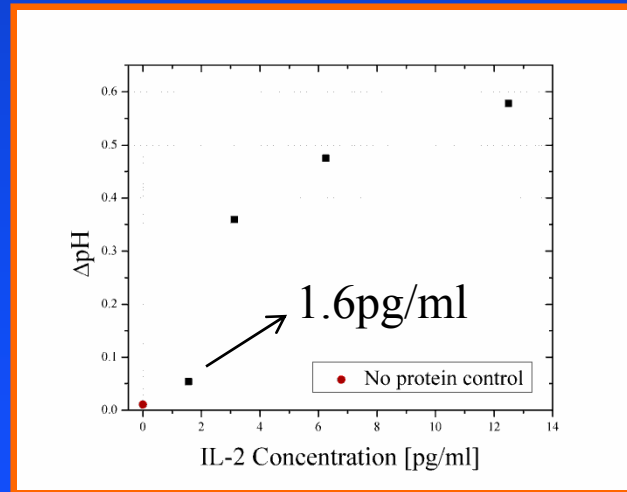
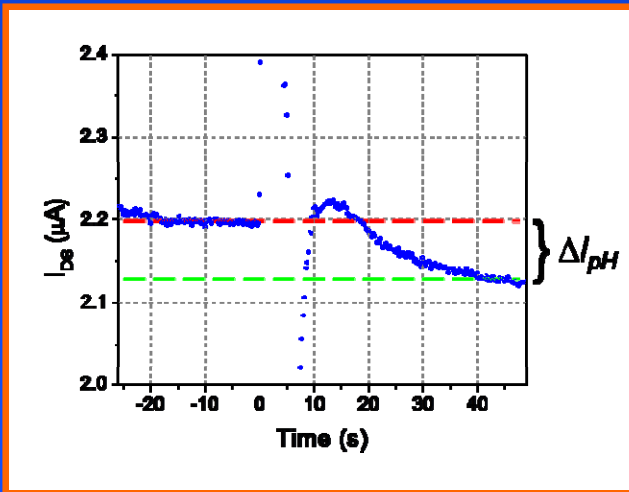
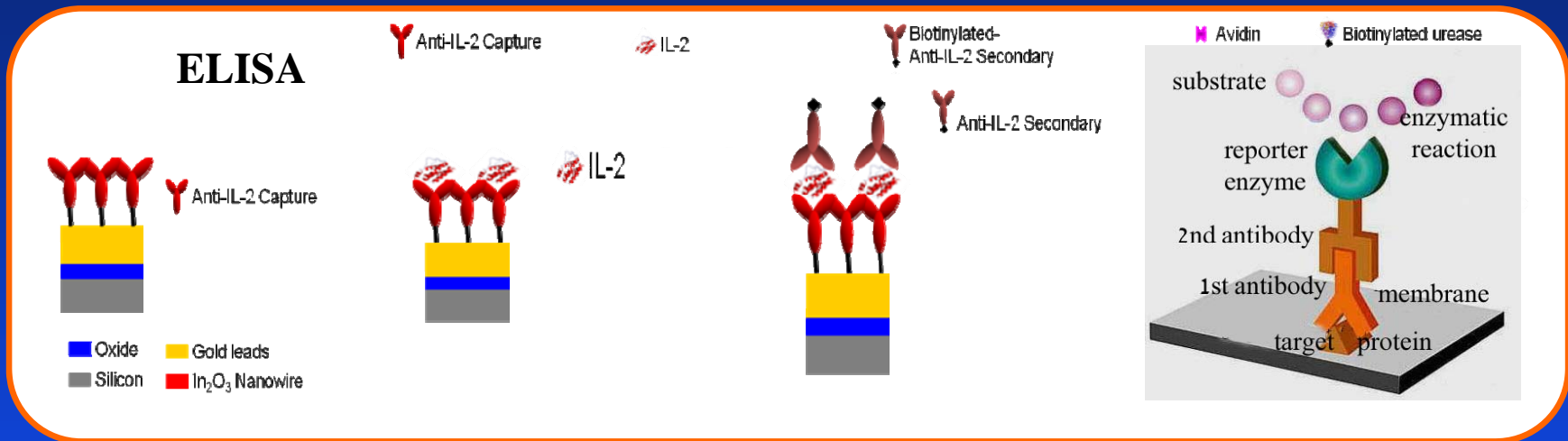


Model system for detecting autoimmune diseases and cancer

Nano Lett. **8**, 3310 (2008)

Nanowire electronic ELISA : ne-ELISA

ELISA: proven method for quantitative & sensitive protein assays
 ne-ELISA: for short λ_{DEBYE} conditions, smaller samples



IL-2 detection limit
 ~ 2 pg/ml –

~10⁴ less molecules
 of protein

Small

DOI:

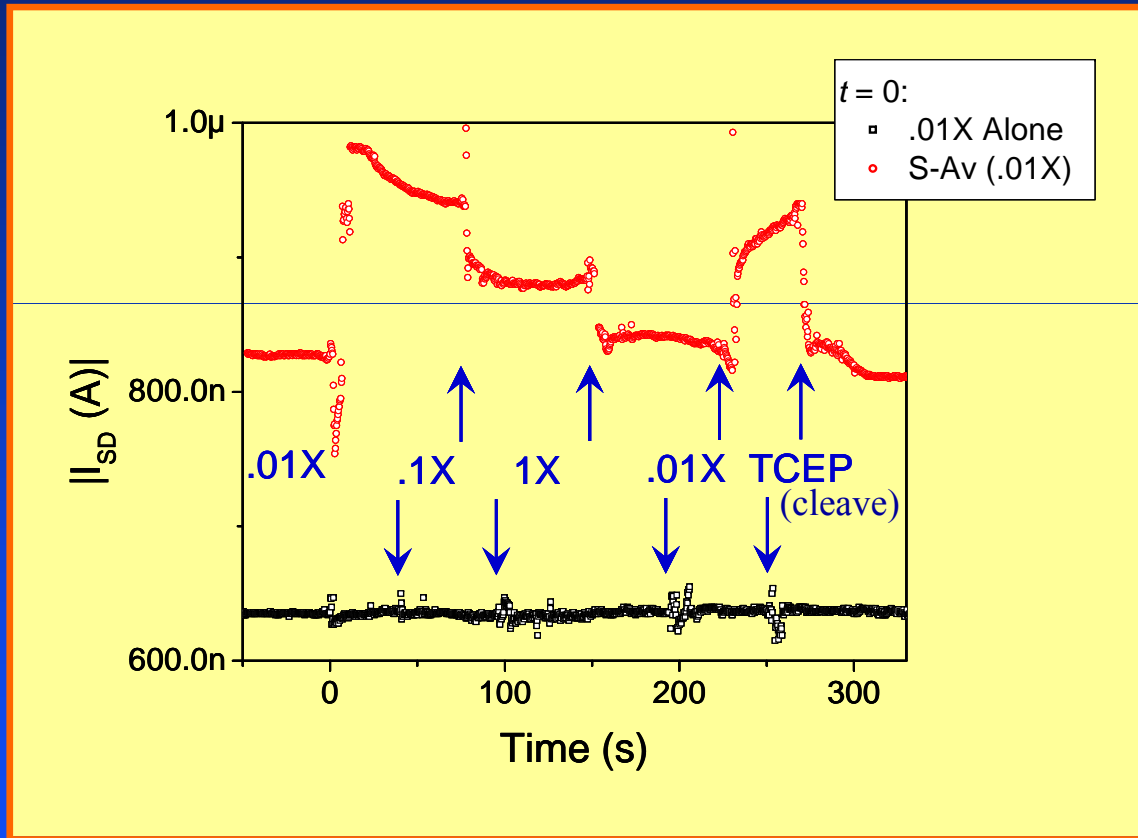
0.1002/sml.200901551

Debye Screening

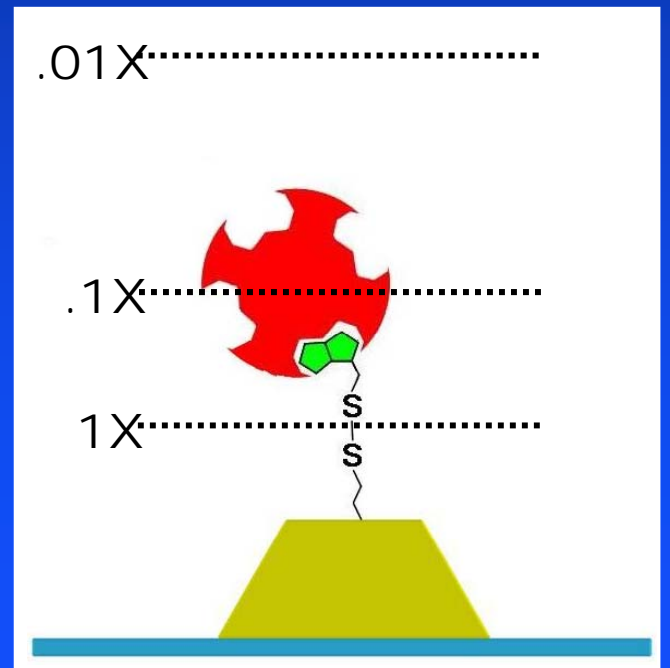
The limitation of NW sensing

$$\lambda_D = \frac{1}{\left(4\pi l_B \sum_i z_i^2 \rho_i\right)^{1/2}}$$

for 0.1 mM PBS,
 $\lambda_D \sim 2.2\text{nm}$



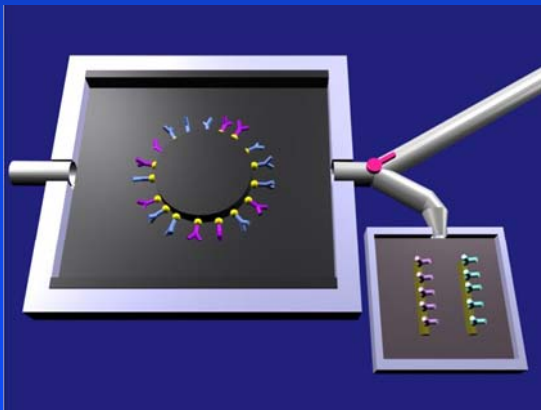
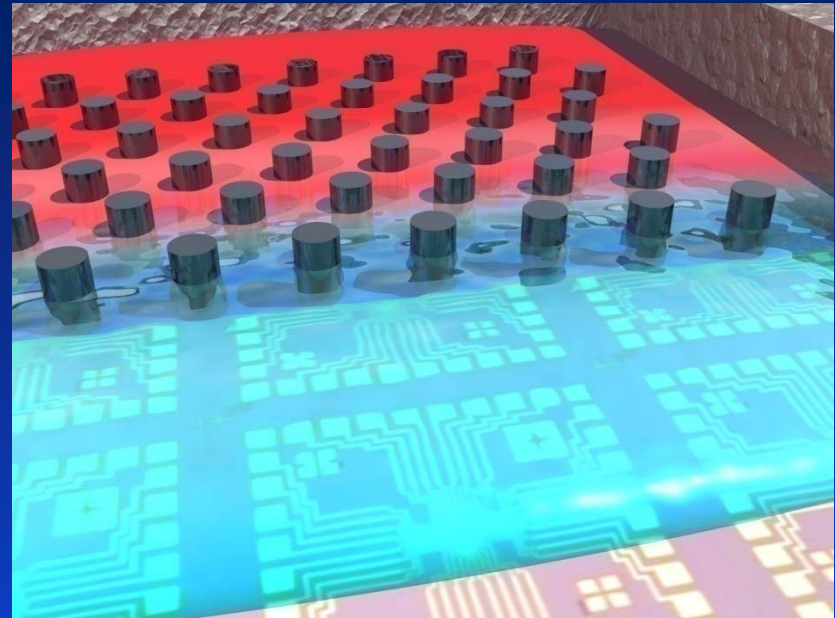
Stern *et al*, *Nano Lett.* 7, 3405 (2007)



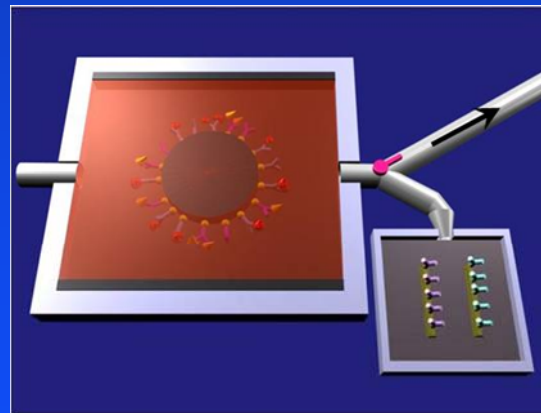
The outstanding challenge: whole blood sensing

- High salt, very short λ_{Debye} ($\sim 0.8\text{nm}$)
- Non-specific binding
- NW detection in blood until now has not been done

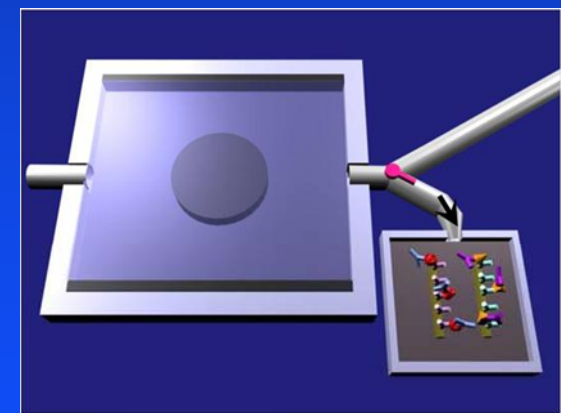
New approach: capture-release



Functionalize C-R region
with 1st antibodies

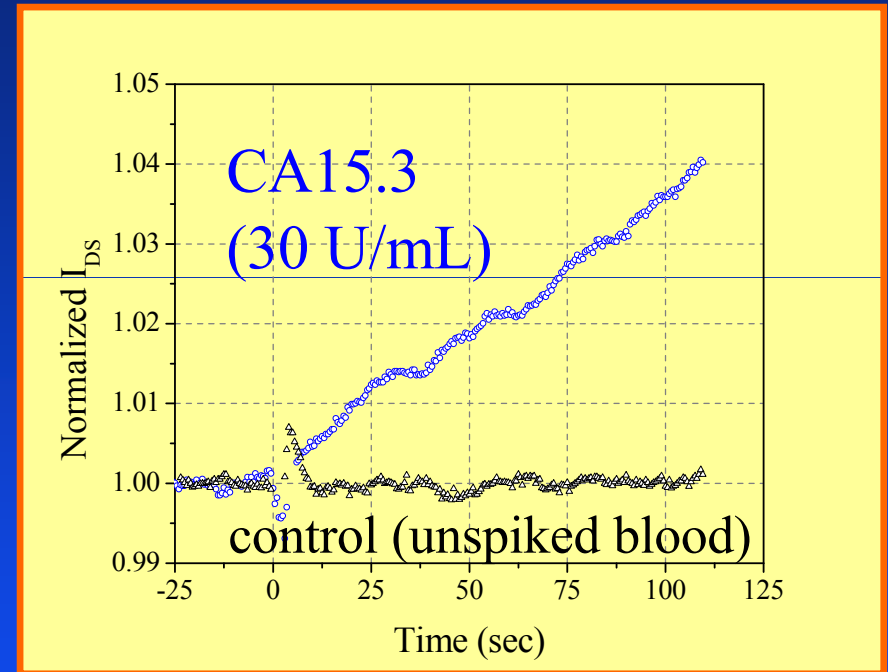
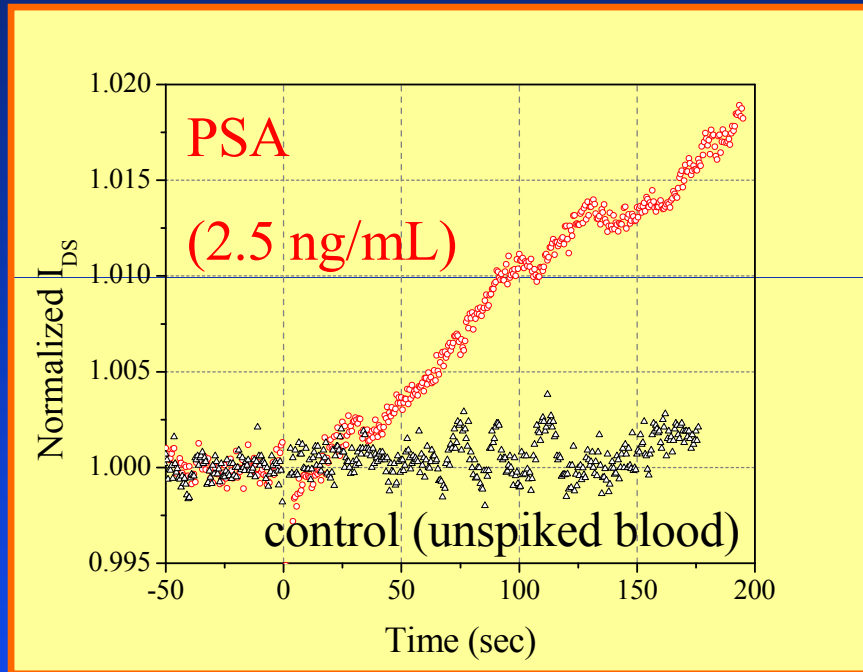


Blood introduction,
protein absorption



Wash, release, capture on
NWs with 2nd antibodies

Simultaneous quantitative measurement of cancer biomarkers using whole blood

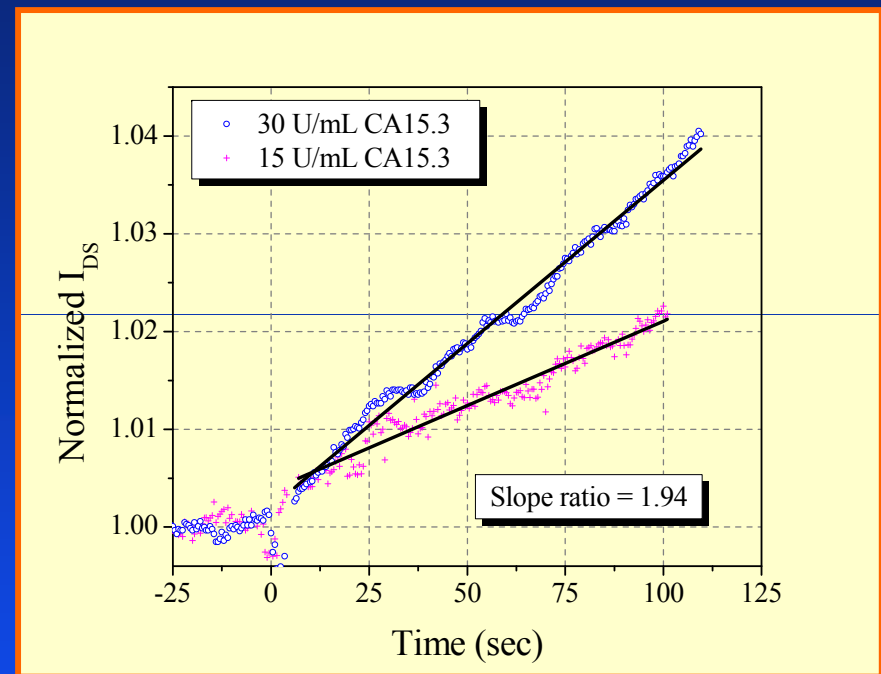
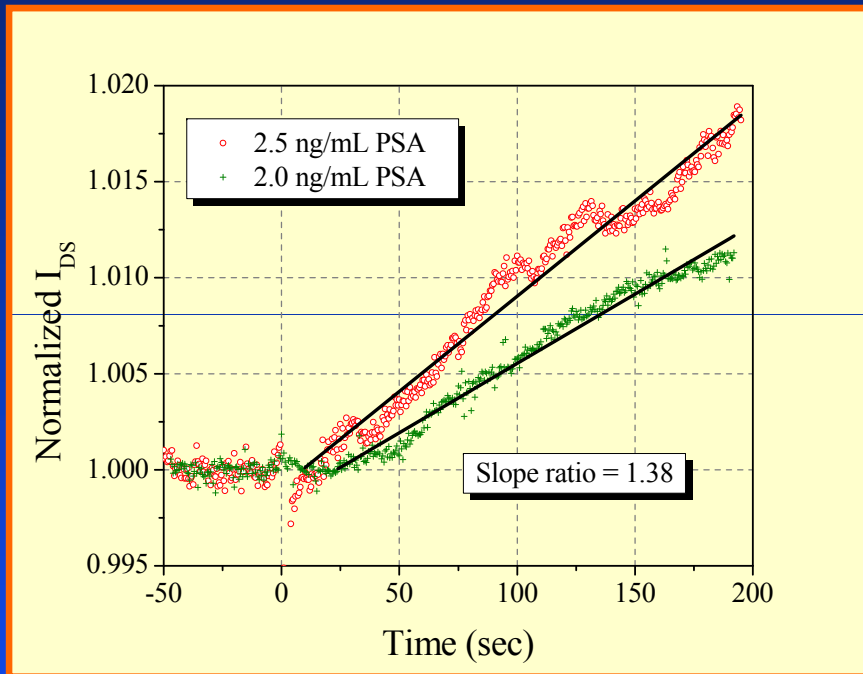


Clinically relevant range , accuracy & reproducibility < 10%
Minimum demonstrated: PSA, .2 ng/mL; CA 15.3, 3 U/mL

Stern et al., *Nature Nanotech.* 5, 138 (2010).

Quantification

Initial rates proportional to analyte concentration



End point detection

VS

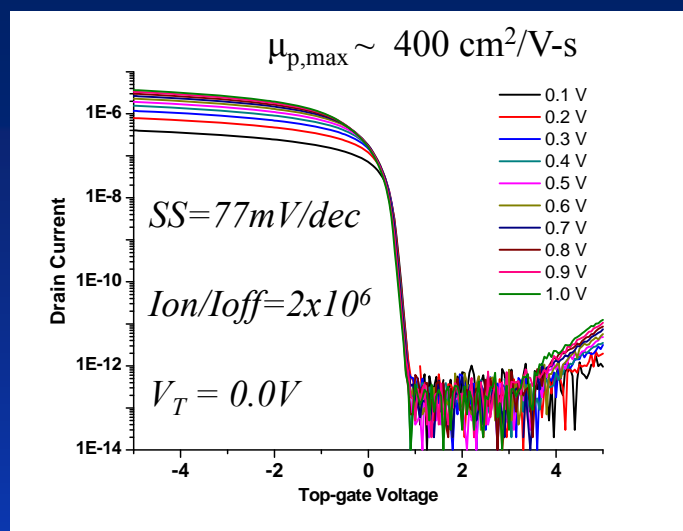
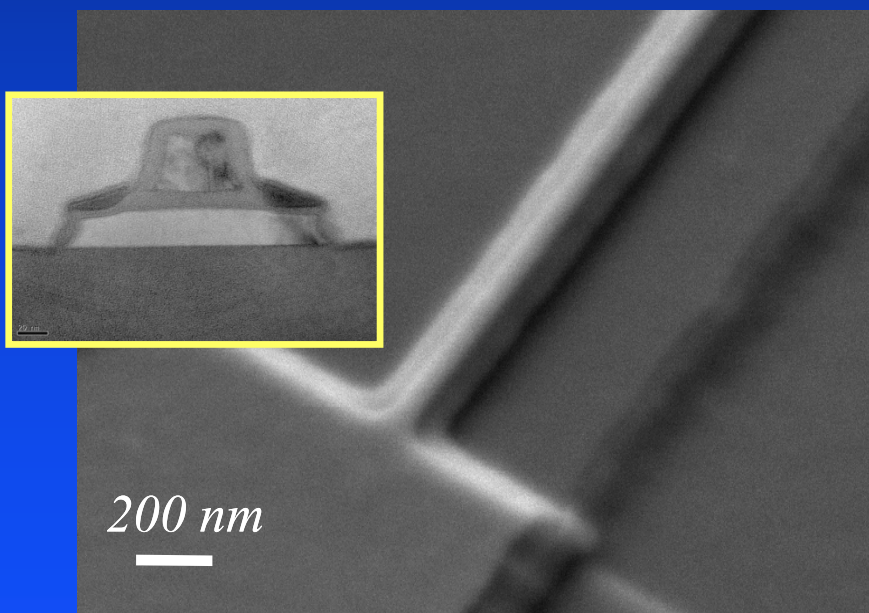
Initial kinetic rates

$$R(t) = \left[\frac{k_a c}{k_a c + k_d} - R_0 \right] (1 - e^{-(k_a c + k_d)t}) + R_0$$

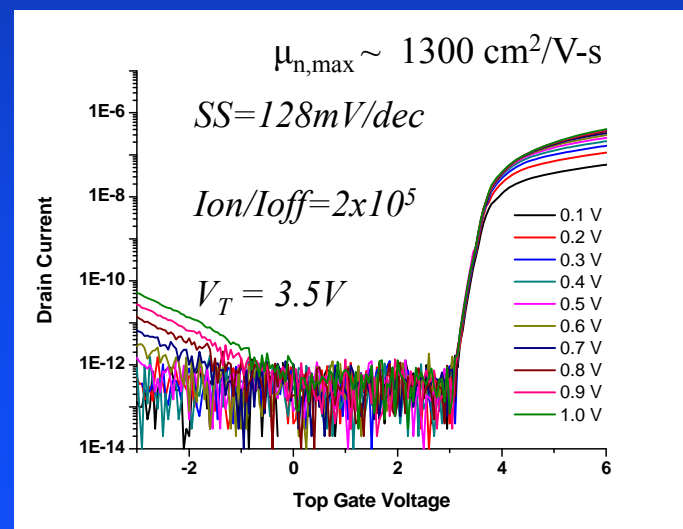
$$\frac{dR}{dt} = k_a c (1 - R) - k_d R$$

Homola J., *Anal Bioanal Chem* (2003) 377:528

Top gated Si NW



p-channel (accumulation)



n-channel (inversion)

Summary

- CMOS-integrable “NWs”
 - Label-free sensing to aM resolution
 - Enables system-level integration
 - Multiplexed
 - Macromolecular assays
 - Interesting device variants
- Real-time cellular immune response
 - Applicable to simple diagnostics
 - Immune response dynamics
- Point-of-care diagnostics
 - multiple biomarker assays, disease discovery
 - whole blood sensing

